



Sample &

Buy



### OPA836, OPA2836

Reference

SLOS712I - JANUARY 2011 - REVISED OCTOBER 2016

OPAx836 Very-Low-Power, Rail-to-Rail Out, Negative Rail In, Voltage-Feedback **Operational Amplifiers** 

Technical

Documents

### Features

- Low Power:
  - Supply Voltage: 2.5 V to 5.5 V
  - Quiescent Current: 1 mA (Typical)
  - Power Down Mode: 0.5 µA (Typical)
- Bandwidth: 205 MHz
- Slew Rate: 560 V/µs
- Rise Time: 3 ns (2 V<sub>STEP</sub>)
- Settling Time (0.1%): 22 ns (2 V<sub>STEP</sub>)
- Overdrive Recovery Time: 60 ns
- SNR: 0.00013% (-117.6 dBc) at 1 kHz (1 V<sub>RMS</sub>)
- THD: 0.00003% (-130 dBc) at 1 kHz (1 V<sub>RMS</sub>)
- HD<sub>2</sub>/HD<sub>3</sub>: -85 dBc/-105 dBc at 1 MHz (2 V<sub>PP</sub>)
- Input Voltage Noise: 4.6 nV/ $\sqrt{Hz}$  (f = 100 kHz)
- Input Offset Voltage: 65 µV (±400-µV Maximum)
- CMRR: 116 dB
- Output Current Drive: 50 mA
- **RRO: Rail-to-Rail Output**
- Input Voltage Range: -0.2 V to +3.9 V (5-V Supply)
- **Operating Temperature Range:** -40°C to +125°C

### 2 Applications

- Low-Power Signal Conditioning
- Audio ADC Input Buffers
- Low-Power SAR and  $\Delta\Sigma$  ADC Drivers
- Portable Systems
- Low-Power Systems
- **High-Density Systems**

### 3 Description

The OPA836 and OPA2836 devices (OPAx836) are single- and dual-channel, ultra-low power, rail-to-rail output, negative-rail input, voltage-feedback (VFB) operational amplifiers designed to operate over a power-supply range of 2.5 V to 5.5 V with a single supply, or  $\pm 1.25$  V to  $\pm 2.75$  V with a dual supply. Consuming only 1 mA per channel and a unity-gain bandwidth of 205 MHz, these amplifiers set an industry-leading power-to-performance ratio for railto-rail amplifiers.

For battery-powered, portable applications where power is of key importance, the low-power consumption and high-frequency performance of the OPA836 and OPA2836 devices offer performanceversus-power capability that is not attainable in other devices. Coupled with a power-savings mode to reduce current to < 1.5  $\mu$ A, these devices offer an attractive solution for high-frequency amplifiers in battery-powered applications.

Support &

Community

2.2

Tools &

Software

The OPA836 RUN package option includes integrated gain-setting resistors for the smallest possible footprint on a printed-circuit board (approximately 2.00 mm x 2.00 mm). By adding circuit traces on the PCB, gains of +1, -1, -1.33, +2, +2.33, -3, +4, -4, +5, -5.33, +6.33, -7, +8 and inverting attenuations of -0.1429, -0.1875, -0.25, -0.33, -0.75 can be achieved. See Table 3 and Table 4 for details.

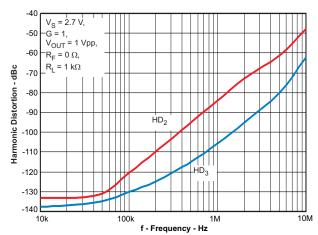
The **OPA836** and OPA2836 devices are characterized for operation over the extended industrial temperature range of -40°C to +125°C.

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)   |  |  |  |  |
|-------------|------------|-------------------|--|--|--|--|
| OPA836      | SOT-23 (6) | 2.90 mm × 1.60 mm |  |  |  |  |
| UPA030      | WQFN (10)  | 2.00 mm × 2.00 mm |  |  |  |  |
|             | SOIC (8)   | 4.90 mm × 3.91 mm |  |  |  |  |
| OPA2836     | VSSOP (10) | 3.00 mm × 3.00 mm |  |  |  |  |
| UPA2030     | UQFN (10)  | 2.00 mm × 2.00 mm |  |  |  |  |
|             | WQFN (10)  | 2.00 mm × 2.00 mm |  |  |  |  |

Device Information<sup>(1)</sup>

(1) For all available packages, see the package option addendum at the end of the data sheet.

### Harmonic Distortion vs Frequency



# Design

# Table of Contents

| Feat | tures 1   |
|------|---|
| Арр  | lications 1   |
| Des  | cription 1  |
| Rev  | ision History 2   |
| OPA  | A836-Related Devices 4  |
| Pin  | Configuration and Functions 4   |
| Spe  | cifications6  |
| 7.1  | Absolute Maximum Ratings 6  |
| 7.2  | ESD Ratings6  |
| 7.3  | Recommended Operating Conditions  |
| 7.4  | Thermal Information: OPA836 6   |
| 7.5  | Thermal Information: OPA2836 7  |
| 7.6  | Electrical Characteristics: $V_S = 2.7 V$   |
| 7.7  | Electrical Characteristics: $V_S = 5 V$   |
| 7.8  | Typical Characteristics 12  |
| Deta | ailed Description   |
| 8.1  | Overview 24   |
| 8.2  | Functional Block Diagrams 24  |
|      | App<br>Des<br>Rev<br>OPA<br>Pin<br>5pe<br>7.1<br>7.2<br>7.3<br>7.4<br>7.5<br>7.6<br>7.7<br>7.8<br>Deta<br>8.1 |

|    | 8.3   | Feature Description                             | 24 |
|----|-------|---|----|
|    | 8.4   | Device Functional Modes                         | 27 |
| 9  | Appl  | lication and Implementation                     | 30 |
|    | 9.1   | Application Information                         | 30 |
|    | 9.2   | Typical Applications                            | 36 |
| 10 | Pow   | er Supply Recommendations                       | 40 |
| 11 | Layo  | out   | 40 |
|    |       | Layout Guidelines                               |    |
|    | 11.2  | Layout Example                                  | 41 |
| 12 |       | ice and Documentation Support                   |    |
|    | 12.1  |   |    |
|    | 12.2  | Related Links                                   | 42 |
|    | 12.3  | Receiving Notification of Documentation Updates | 42 |
|    | 12.4  | Community Resources                             | 42 |
|    | 12.5  | Trademarks                                      | 42 |
|    | 12.6  | Electrostatic Discharge Caution                 | 42 |
|    | 12.7  | Glossary  | 42 |
| 13 | Мес   | hanical, Packaging, and Orderable               |    |
|    | Infor | mation  | 43 |
|    |       |   |    |

# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Cł | nanges from Revision H (September 2016) to Revision I   | Page |
|----|---|------|
| •  | Changed text in sections throughout the data sheet to be more clear and concise   | 1    |
| •  | Changed " $R_G = \infty \Omega$ (open)" to " $R_G$ = open"  | 32   |
| •  | Changed "gain tracking is superior to using" to "gain drift is superior to the drift with"  | 33   |
| •  | Changed "results in degraded harmonic distortion" to "increases the harmonic distortion"  | 37   |
| •  | Deleted "A 10- $\Omega$ series resistor can be inserted between the capacitor and the noninverting pin to isolate the capacitance." | 38   |

### Changes from Revision G (October 2015) to Revision H

| • | Changed "Type" column header to "I/O" on Pin Functions table  | . 5 |
|---|---|-----|
|   | Reformatted header rows in Thermal Information: OPA836 and Thermal Information: OPA2836 tables                    |     |
| • | Reformatted Thermal Information table note  | . 6 |
| • | Reformatted Thermal Information table note  | . 7 |
| • | Deleted the word "linear" from Output section parameters in <i>Electrical Characteristics</i> $V_S = 2.7 V$ table | . 7 |
| • | Deleted the word "linear" from Output section parameters in <i>Electrical Characteristics</i> $V_S = 5 V$ table   | . 9 |
| • | Reformatted Development Support subsection  | 42  |
| • | Reformatted Related Documentation section   | 42  |
| • | Added Receiving Notification of Documentation Updates section   | 42  |

### Changes from Revision E (September 2013) to Revision F

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# Page

Page

TEXAS INSTRUMENTS

#### www.ti.com

SLOS712I – JANUARY 2011 – REVISED OCTOBER 2016

### Changes from Revision D (October 2011) to Revision E

| • | Added OPA2836 RMC package to document                                  | 1 |
|---|--|---|
|   | Added RMC pin definitions to <i>Pin Functions</i> table                |   |
| • | Deleted Packaging/Ordering Information table, leaving only note to POA | 6 |
| • | Added OPA2836 RMC package to Thermal Information table                 | 7 |
|   |  |   |

### Changes from Revision C (September 2011) to Revision D

#### Page

Page

| • | Removed Product Preview from OPA835IRUNT and OPA835IRUNR                                       |
|---|--|
| • | Removed Product Preview from OPA836IRUNT and OPA836IRUNR                                       |
| • | Changed typical value for resistor temperature coefficien parameter from TBD to < 10           |
| • | Changed "quiescent operating current" parameter to "quiescent operating current per amplifier" |
| • | Changed resistor temperature coefficient typical value from TBD to < 10 11                     |
| • | Changed "quiescent operating current" to "quiescent operating current per amplifier"           |

### Changes from Revision B (May 2011) to Revision C

### Page

| • | Added the "The OPA836 RUN package" text to the Description  | . 1 |
|---|---|-----|
| • | Removed Product Preview from all devices except OPA835IRUNT and OPA835IRUNR   | . 4 |
| • | Removed Product Preview from all devices except OPA836IRUNT and OPA836IRUNR   | . 6 |
| • | Changed typical value for channel to channel crosstalk (OPA2836) parameter from TBD to -120 dB                                  | . 8 |
| • | Changed the common-mode rejection ratio minimum value from 94 dB to 91 dB   | . 8 |
| • | Added Gain Setting Resistors (OPA836IRUN ONLY) parameter in <i>Electrical Characteristics</i> table                             | . 9 |
| • | Changed the quiescent operating current ( $T_A = 25^{\circ}C$ ) minimum value from 0.8 mA to 0.7 mA                             | . 9 |
| • | Changed the minimum value for power supply rejection (±PSRR) parameter from 95 dB to 91 dB                                      | . 9 |
| • | Changed the power-down pin bias current test condition from $\overline{PD} = 0.7$ V to $\overline{PD} = 0.5$ V                  | . 9 |
| • | Changed the power-down quiescent current test condition from $\overline{PD} = 0.7 \text{ V}$ to $\overline{PD} = 0.5 \text{ V}$ | . 9 |
| • | Changed typical value for channel to channel crosstalk (OPA2836) parameter from TBD to -120 dB                                  | 10  |
| • | Changed the Common-mode rejection ratio Min value From: 97 dB To: 94 dB   | 11  |
| • | Added GAIN SETTING RESISTORS (OPA836I RUN ONLY) parameter to Electrical Characteristics table                                   | 11  |
| • | Changed the quiescent operating current ( $T_A = 25^{\circ}C$ ) minimum value from 0.9 mA to 0.8 mA                             | 11  |
| • | Changed the power supply rejection (±PSRR) minimum value from: 97 dB to 94 dB   | 11  |
| • | Changed the Power-down quiescent current CONDITIONS From: PD = 0.7 V To: PD = 0.5 V   | 11  |
| • | Changed the Power-down quiescent current Conditions From: PD = 0.7 V To: PD = 0.5 V   | 11  |
| • | Added Figure Crosstalk vs Frequency   | 16  |
| • | Added Crosstalk vs Frequency figure   | 22  |
| • | Added section Single Ended to Differential Amplifier  | 31  |

Page

### Changes from Revision A (March 2011) to Revision B

Changed OPA836 from product preview to production data......1

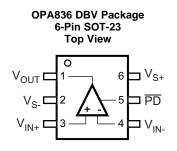
4

### 5 OPA836-Related Devices

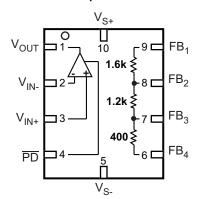
| DEVICE  | BW (A <sub>V</sub> = 1)<br>(MHz) | SLEW RATE<br>(V/µs) | lq (+5 V)<br>(mA) | INPUT NOISE<br>(nV/√Hz) | RAIL-TO-RAIL IN/OUT | DUALS   |
|---------|----------------------------------|---------------------|-------------------|-------------------------|---------------------|---------|
| OPA836  | 205                              | 560                 | 1                 | 4.6                     | -VS/Out             | OPA2836 |
| OPA835  | 30                               | 110                 | 0.25              | 9.3                     | -VS/Out             | OPA2835 |
| OPA365  | 50                               | 25                  | 5                 | 4.5                     | In/Out              | OPA2365 |
| THS4281 | 95                               | 35                  | 0.75              | 12.5                    | In/Out              |         |
| LMH6618 | 140                              | 45                  | 1.25              | 10                      | In/Out              | LMH6619 |
| OPA830  | 310                              | 600                 | 3.9               | 9.5                     | -VS/Out             | OPA2830 |

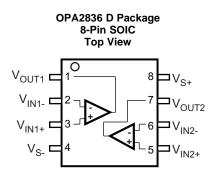
For a complete selection of TI High Speed Amplifiers, visit ti.com.

# 6 Pin Configuration and Functions

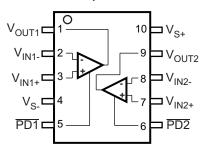


OPA836 RUN Package 10-Pin WQFN Top View











#### OPA2836 RUN, RMC Packages 10-Pin WQFN, UQFN Top View $V_{S+}$ ∐ 10 V<sub>OUT1</sub> 9 🗖 $V_{OUT2}$ V<sub>IN1</sub> -8 🗆 V<sub>IN2-</sub> ٦2 $V_{IN2+}$ $V_{IN1+}$ **3** 7 C PD2 PD1 34 6 **C** 5 Π

### **Pin Functions**

V<sub>S-</sub>

| PIN               |        |      |         |       |               |                      |   |  |
|-------------------|--------|------|---------|-------|---------------|----------------------|---|--|
|                   | OPA836 |      | OPA2836 |       | I/O           | DESCRIPTION          |   |  |
| NAME              | SOT-23 | WQFN | SOIC    | VSSOP | WQFN,<br>UQFN | ., e                 |   |  |
| FB <sub>1</sub>   |        | 9    |         |       |               | I/O                  | Connection to top of 2.4-k $\Omega$ internal gain setting resistors                           |  |
| FB <sub>2</sub>   |        | 8    |         |       |               | I/O                  | Connection to junction of 1.8-k $\Omega$ and 2.4-k $\Omega$ internal gain setting resistors   |  |
| FB <sub>3</sub>   |        | 7    |         | _     | _             | I/O                  | Connection to junction of 600- $\Omega$ and 1.8-k $\Omega$ internal gain setting resistors    |  |
| FB <sub>4</sub>   |        | 6    |         |       |               | I/O                  | Connection to bottom of 600- $\Omega$ internal gain setting resistors                         |  |
| PD                | 5      | 4    | _       |       |               | I                    | Amplifier Power Down, low = low-power mode,<br>high = normal operation (PIN MUST BE DRIVEN)   |  |
| PD1               |        |      |         | 5     | 4             | I                    | Amplifier 1 Power Down, low = low-power mode,<br>high = normal operation (PIN MUST BE DRIVEN) |  |
| PD2               |        | _    |         | 6     | 6             | I                    | Amplifier 2 Power Down, low = low-power mode,<br>high = normal operation (PIN MUST BE DRIVEN) |  |
| V <sub>IN+</sub>  | 3      | 3    |         |       |               | I                    | Amplifier noninverting input  |  |
| $V_{IN-}$         | 4      | 2    |         | _     | _             | I                    | Amplifier inverting input   |  |
| V <sub>IN1+</sub> |        |      | 3       | 3     | 3             | I                    | Amplifier 1 noninverting input  |  |
| V <sub>IN1-</sub> |        |      | 2       | 2     | 2             | I                    | Amplifier 1 inverting input   |  |
| V <sub>IN2+</sub> | _      | _    | 5       | 7     | 7             | I                    | Amplifier 2 noninverting input  |  |
| V <sub>IN2-</sub> |        |      | 6       | 8     | 8             | I                    | Amplifier 2 inverting input   |  |
| V <sub>OUT</sub>  | 1      | 1    |         |       | _             | 0                    | Amplifier output  |  |
| V <sub>OUT1</sub> |        |      | 1       | 1     | 1             | 0                    | Amplifier 1 output  |  |
| V <sub>OUT2</sub> | ] —    |      | 7       | 9     | 9             | O Amplifier 2 output |   |  |
| V <sub>S+</sub>   | 6      | 10   | 8       | 10    | 10            | POW                  | Positive power supply input   |  |
| V <sub>S-</sub>   | 2      | 5    | 4       | 4     | 5             | POW                  | Negative power supply input   |  |

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### 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                      |                                | MIN                  | MAX   | UNIT |
|----------------------|--------------------------------|----------------------|---|------|
| $V_{S-}$ to $V_{S+}$ | Supply voltage                 |                      | 5.5   | V    |
| VI                   | Input voltage                  | V <sub>S-</sub> -0.7 | V <sub>S+</sub> + 0.7                         | V    |
| V <sub>ID</sub>      | Differential input voltage     |                      | 1   | V    |
| I <sub>I</sub>       | Continuous input current       |                      | 0.85  | mA   |
| Io                   | Continuous output current      |                      | 60  | mA   |
|                      | Continuous power dissipation   |                      | nformation: OPA836<br>and<br>rmation: OPA2836 |      |
| TJ                   | Maximum junction temperature   |                      | 150   | °C   |
| T <sub>A</sub>       | Operating free-air temperature | -40                  | 125   | °C   |
| T <sub>stg</sub>     | Storage temperature            | -65                  | 150   | °C   |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 7.2 ESD Ratings

|                    |       |   |  | VALUE | UNIT |
|--------------------|-------|---|--|-------|------|
| V <sub>(ESD)</sub> |       | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup> | ±6000  |       |      |
|                    | (ESD) | Electrostatic discharge   | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1000 | V    |
|                    |       |   | Machine model  | ±200  |      |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                 |                       | MIN | NOM | MAX | UNIT |
|-----------------|-----------------------|-----|-----|-----|------|
| V <sub>S+</sub> | Single supply voltage | 2.5 | 5   | 5.5 | V    |
| T <sub>A</sub>  | Ambient temperature   | -40 | 25  | 125 | °C   |

### 7.4 Thermal Information: OPA836

|                      |  | OPA           | OPA836            |      |
|----------------------|--|---------------|-------------------|------|
|                      | THERMAL METRIC <sup>(1)</sup>                | DBV (SOT23-6) | RUN (WQFN-<br>10) | UNIT |
|                      |  | 6 PINS        | 10 PINS           |      |
| $R_{	ext{	heta}JA}$  | Junction-to-ambient thermal resistance       | 194           | 145.8             | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance    | 129.2         | 75.1              | °C/W |
| $R_{\theta JB}$      | Junction-to-board thermal resistance         | 39.4          | 38.9              | °C/W |
| ΨJT                  | Junction-to-top characterization parameter   | 25.6          | 13.5              | °C/W |
| Ψјв                  | Junction-to-board characterization parameter | 38.9          | 104.5             | °C/W |

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics (SPRA953).

#### OPA836, OPA2836

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### 7.5 Thermal Information: OPA2836

|                    |  |            | OPA2836                 |                  |                  |      |  |  |
|--------------------|--|------------|-------------------------|------------------|------------------|------|--|--|
|                    | THERMAL METRIC <sup>(1)</sup>                | D (SOIC-8) | (DGS) VSSOP,<br>MSOP-10 | (RUN)<br>WQFN-10 | RMC<br>(UQFN-10) | UNIT |  |  |
|                    |  | 8 PINS     | 10 PINS                 | 10 PINS          | 10 PINS          |      |  |  |
| $R_{\thetaJA}$     | Junction-to-ambient thermal resistance       | 150.1      | 206                     | 145.8            | 143.2            | °C/W |  |  |
| $R_{\theta JCtop}$ | Junction-to-case (top) thermal resistance    | 83.8       | 75.3                    | 75.1             | 49.0             | °C/W |  |  |
| $R_{\theta JB}$    | Junction-to-board thermal resistance         | 68.4       | 96.2                    | 38.9             | 61.9             | °C/W |  |  |
| ΨJT                | Junction-to-top characterization parameter   | 33.0       | 12.9                    | 13.5             | 3.3              | °C/W |  |  |
| Ψјв                | Junction-to-board characterization parameter | 67.9       | 94.6                    | 104.5            | 61.9             | °C/W |  |  |

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics (SPRA953).

### 7.6 Electrical Characteristics: V<sub>s</sub> = 2.7 V

at  $V_{S+}$  = +2.7 V,  $V_{S-}$  = 0 V,  $V_{OUT}$  = 1  $V_{PP}$ ,  $R_F$  = 0  $\Omega$ ,  $R_L$  = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply,  $V_{IN\_CM}$  = mid-supply – 0.5 V.  $T_A$  = 25°C, unless otherwise noted.

| PARAMETER                               | TEST CONDITIONS   | MIN TYP MA   |        | TEST<br>LEVEL <sup>(1)</sup> |
|---|---|--|--------|------------------------------|
| AC PERFORMANCE                          |   |  | ·      |                              |
|   | $V_{OUT}$ = 100 m $V_{PP}$ , G = 1  | 200  |        |                              |
| Small-signal bandwidth                  | $V_{OUT}$ = 100 m $V_{PP}$ , G = 2  | 100  | MHz    | с                            |
|   | $V_{OUT}$ = 100 m $V_{PP}$ , G = 5  | V <sub>OUT</sub> = 100 mV <sub>PP</sub> , G = 5 26 |        | C                            |
|   | $V_{OUT} = 100 \text{ mV}_{PP}, \text{ G} = 10$   | 11   |        |                              |
| Gain-bandwidth product                  | V <sub>OUT</sub> = 100 mV <sub>PP</sub> , G = 10  | 110  | MHz    | С                            |
| Large-signal bandwidth                  | V <sub>OUT</sub> = 1 V <sub>PP</sub> , G = 2  | 60   | MHz    | С                            |
| Bandwidth for 0.1-dB flatness           | V <sub>OUT</sub> = 1 V <sub>PP</sub> , G = 2  | 25   | MHz    | С                            |
| Slew rate, rise                         | $V_{OUT} = 1 V_{STEP}, G = 2$   | 260  | V/µs   | С                            |
| Slew rate, fall                         | $V_{OUT} = 1 V_{STEP}, G = 2$   | 240  | V/µs   | С                            |
| Rise time                               | $V_{OUT} = 1 V_{STEP}, G = 2$   | 4  | ns     | С                            |
| Fall time                               | $V_{OUT} = 1 V_{STEP}, G = 2$   | 4.5  | ns     | С                            |
| Settling time to 1%, rise               | $V_{OUT} = 1 V_{STEP}, G = 2$   | 15   | ns     | С                            |
| Settling time to 1%, fall               | $V_{OUT} = 1 V_{STEP}, G = 2$   | 15   | ns     | С                            |
| Settling time to 0.1%, rise             | $V_{OUT} = 1 V_{STEP}, G = 2$   | 30   | ns     | С                            |
| Settling time to 0.1%, fall             | $V_{OUT} = 1 V_{STEP}, G = 2$   | 25   | ns     | С                            |
| Settling time to 0.01%, rise            | $V_{OUT} = 1 V_{STEP}, G = 2$   | 50   | ns     | С                            |
| Settling time to 0.01%, fall            | $V_{OUT} = 1 V_{STEP}, G = 2$   | 45   | ns     | С                            |
| Overshoot/Undershoot                    | $V_{OUT} = 1 V_{STEP}, G = 2$   | 5%/3%  |        | С                            |
|   | f = 10 kHz, $V_{IN\_CM}$ = mid-supply – 0.5 V   | -133   |        | С                            |
| Second-order harmonic distortion        | f = 100 kHz, $V_{IN\_CM}$ = mid-supply – 0.5 V  | -120   | dBc    | С                            |
|   | f = 1 MHz, $V_{IN\_CM}$ = mid-supply - 0.5 V  | -84  |        | С                            |
|   | f = 10 kHz, $V_{IN\_CM}$ = mid-supply – 0.5 V   | -137   |        | С                            |
| Third-order harmonic distortion         | f = 100 kHz, $V_{IN\_CM}$ = mid-supply – 0.5 V  | -130   | dBc    | С                            |
|   | f = 1 MHz, $V_{IN\_CM}$ = mid-supply - 0.5 V  | -105   |        | С                            |
| Second-order intermodulation distortion | $      f = 1 \text{ MHz}, 200\text{-kHz Tone Spacing}, \\ V_{OUT} \text{ Envelope} = 1 \text{ V}_{PP} \\ V_{IN\_CM} = \text{mid-supply} - 0.5 \text{ V} $ | -90  | dBc    | с                            |
| Third-order intermodulation distortion  | $    f = 1 \text{ MHz}, 200\text{-kHz Tone Spacing}, \\ V_{OUT} \text{ Envelope} = 1 \text{ V}_{PP} \\ V_{IN\_CM} = \text{mid-supply} - 0.5 \text{ V} $   | -90  | dBc    | С                            |
| Input voltage noise                     | f = 100 KHz   | 4.6  | nV/√Hz | С                            |
| Voltage noise 1/f corner frequency      |   | 215  | Hz     | С                            |
| Input current noise                     | f = 1 MHz   | 0.75   | pA/√Hz | С                            |

(1) Test levels (all values set by characterization and simulation): (A) 100% tested at 25°C; over temperature limits by characterization and simulation. (B) Not tested in production; limits set by characterization and simulation. (C) Typical value only for information.



### Electrical Characteristics: V<sub>s</sub> = 2.7 V (continued)

at  $V_{S+}$  = +2.7 V,  $V_{S-}$  = 0 V,  $V_{OUT}$  = 1  $V_{PP}$ ,  $R_F$  = 0  $\Omega$ ,  $R_L$  = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply,  $V_{IN\_CM}$  = mid-supply - 0.5 V.  $T_A$  = 25°C, unless otherwise noted.

| PARAMETER                                 | TEST CONDITIONS   | MIN   | ТҮР             | МАХ  | UNIT                   | TEST<br>LEVEL <sup>(1)</sup> |
|---|---|-------|-----------------|------|------------------------|------------------------------|
| AC PERFORMANCE (continued)                |   |       |                 |      |                        |                              |
| Current noise 1/f corner frequency        |   |       | 31.7            |      | kHz                    | С                            |
| Overdrive recovery time, over/under       | Overdrive = 0.5 V   |       | 55/60           |      | ns                     | С                            |
| Closed-loop output impedance              | f = 100 kHz   |       | 0.02            |      | Ω                      | С                            |
| Channel-to-channel crosstalk (OPA2836)    | f = 10 kHz  |       | -120            |      | dB                     | С                            |
| DC PERFORMANCE                            |   |       |                 |      |                        |                              |
| Open-loop voltage gain (A <sub>OL</sub> ) |   | 100   | 125             |      | dB                     | А                            |
|   | $T_A = 25^{\circ}C$   | -400  | ±65             | 400  |                        | А                            |
|   | $T_A = 0^{\circ}C$ to $70^{\circ}C$                                 | -680  |                 | 680  | .,                     |                              |
| Input referred offset voltage             | $T_A = -40^{\circ}C$ to $85^{\circ}C$                               | -760  |                 | 760  | μV                     | В                            |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$                              | -1060 |                 | 1060 |                        |                              |
|   | $T_A = 0^{\circ}C$ to $70^{\circ}C$                                 | -6.2  | ±1              | 6.2  |                        |                              |
| Input offset voltage drift <sup>(2)</sup> | $T_A = -40^{\circ}C$ to $85^{\circ}C$                               | 6     | ±1              | 6    | µV/°C                  | В                            |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$                              | -6.6  | ±1.1            | 6.6  |                        |                              |
|   | T <sub>A</sub> = 25°C   | 300   | 650             | 1000 |                        | А                            |
| Input bias current <sup>(3)</sup>         | $T_A = 0^{\circ}C$ to $70^{\circ}C$                                 | 190   |                 | 1400 |                        | В                            |
|   | $T_A = -40^{\circ}C$ to $85^{\circ}C$                               | 120   |                 | 1500 | nA                     |                              |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$                              | 120   |                 | 1800 |                        |                              |
| Input bias current drift <sup>(2)</sup>   | $T_A = 0^{\circ}C$ to $70^{\circ}C$                                 | -2    | ±0.33           | 2    | nA/°C                  |                              |
|   | $T_A = -40^{\circ}C$ to $85^{\circ}C$                               | -1.9  | ±0.32           | 1.9  |                        | В                            |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$                              | -2.1  | ±0.37           | 2.1  |                        |                              |
|   | $T_A = 25^{\circ}C$   | -180  | ±30             | 180  |                        | А                            |
|   | $T_A = 0^{\circ}C$ to $70^{\circ}C$                                 | -200  | ±30             | 200  |                        |                              |
| Input offset current                      | $T_A = -40^{\circ}C$ to $85^{\circ}C$                               | -215  | ±30             | 215  | nA                     | В                            |
|   | $T_A = -40^{\circ}C$ to 125°C                                       | -240  | ±30             | 240  |                        |                              |
|   | $T_A = 0^{\circ}C$ to 70°C  | -460  | ±77             | 460  |                        |                              |
| Input offset current drift <sup>(2)</sup> | $T_A = -40^{\circ}C$ to $85^{\circ}C$                               | -575  | ±95             | 575  | pA/°C                  | В                            |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$                              | -600  | ±100            | 600  | -                      |                              |
| INPUT                                     |   |       |                 |      |                        | 1                            |
| <b>0</b>                                  | T <sub>A</sub> = 25°C,<br>< 3-dB degradation in CMRR limit          |       | -0.2            | 0    | V                      | А                            |
| Common-mode input range low               | $T_A = -40^{\circ}$ C to 125°C,<br>< 3-dB degradation in CMRR limit |       | -0.2            | 0    | V                      | В                            |
| Common modo input rango high              | $T_A = 25^{\circ}C$ ,<br>< 3-dB degradation in CMRR limit           | 1.5   | 1.6             |      | V                      | А                            |
| Common-mode input range high              | $T_A = -40^{\circ}$ C to 125°C,<br>< 3-dB degradation in CMRR limit | 1.5   | 1.6             |      | V                      | В                            |
| Input operating voltage range             | $T_A = 25^{\circ}C$ ,<br>< 6-dB degradation in THD                  |       | –0.3 to<br>1.75 |      | V                      | С                            |
| Common-mode rejection ratio               |   | 91    | 114             |      | dB                     | А                            |
| Input impedance common-mode               |   | 2     | 200    1.2      |      | $k\Omega \parallel pF$ | С                            |
| Input impedance differential mode         |   |       | 200    1        |      | kΩ∥pF                  | С                            |

(2) Input Offset Voltage Drift, Input Bias Current Drift, and Input Offset Current Drift are average values calculated by taking data at the end points, computing the difference, and dividing by the temperature range.

(3) Current is considered positive out of the pin.



### Electrical Characteristics: V<sub>s</sub> = 2.7 V (continued)

at  $V_{S+}$  = +2.7 V,  $V_{S-}$  = 0 V,  $V_{OUT}$  = 1  $V_{PP}$ ,  $R_F$  = 0  $\Omega$ ,  $R_L$  = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply,  $V_{IN\_CM}$  = mid-supply - 0.5 V.  $T_A$  = 25°C, unless otherwise noted.

| PARAMETER                                 | TEST CONDITIONS   | MIN  | TYP   | МАХ  | UNIT | TEST<br>LEVEL <sup>(1)</sup> |
|---|---|------|-------|------|------|------------------------------|
| OUTPUT                                    |   |      |       |      |      |                              |
|   | $T_A = 25^{\circ}C, G = 5$  |      | 0.15  | 0.2  | V    | А                            |
| Output voltage low                        | $T_{A} = -40^{\circ}C$ to 125°C, G = 5                                      |      | 0.15  | 0.2  | V    | В                            |
| Outrast units on high                     | $T_{A} = 25^{\circ}C, G = 5$  | 2.45 | 2.5   |      | V    | А                            |
| Output voltage high                       | $T_{A} = -40^{\circ}C$ to 125°C, G = 5                                      | 2.45 | 2.5   |      | V    | В                            |
| Output saturation voltage, high/low       | T <sub>A</sub> = 25°C, G = 5  |      | 80/40 |      | mV   | С                            |
|   | $T_A = 25^{\circ}C$   | ±40  | ±45   |      | mA   | А                            |
| Output current drive                      | $T_A = -40^{\circ}C$ to $125^{\circ}C$                                      | ±40  | ±45   |      | mA   | В                            |
| GAIN SETTING RESISTORS (OPA836IRUN O      | NLY)  |      |       |      |      |                              |
| Resistor FB1 to FB2                       | DC resistance   | 1584 | 1600  | 1616 | Ω    | А                            |
| Resistor FB2 to FB3                       | DC resistance   | 1188 | 1200  | 1212 | Ω    | А                            |
| Resistor FB3 to FB4                       | DC resistance   | 396  | 400   | 404  | Ω    | А                            |
| Resistor tolerance                        | DC resistance   | -1%  |       | 1%   |      | А                            |
| Resistor temperature coefficient          | DC resistance   |      | <10   |      | PPM  | С                            |
| POWER SUPPLY                              |   |      |       |      |      |                              |
| Specified operating voltage               |   | 2.5  |       | 5.5  | V    | В                            |
|   | $T_A = 25^{\circ}C$   | 0.7  | 0.95  | 1.15 | mA   | А                            |
| Quiescent operating current per amplifier | $T_A = -40^{\circ}C$ to $125^{\circ}C$                                      | 0.6  |       | 1.4  | mA   | В                            |
| Power supply rejection (±PSRR)            |   | 91   | 108   |      | dB   | А                            |
| POWER DOWN                                | <u>-</u>  |      |       |      |      |                              |
| Enable voltage threshold                  | Specified "on" above V <sub>S-</sub> + 2.1 V                                |      |       | 2.1  | V    | А                            |
| Disable voltage threshold                 | Specified "off" below V <sub>S-</sub> + 0.7 V                               | 0.7  |       |      | V    | А                            |
| Power-down pin bias current               | PD = 0.5 V  |      | 20    | 500  | nA   | A                            |
| Power-down quiescent current              | PD = 0.5 V  |      | 0.5   | 1.5  | μA   | А                            |
| Turnon time delay                         | Time from $\overline{PD}$ = high to V <sub>OUT</sub> = 90% of final value   |      | 200   |      | ns   | С                            |
| Turnoff time delay                        | Time from $\overline{PD}$ = low to V <sub>OUT</sub> = 10% of original value |      | 25    |      | ns   | С                            |

### 7.7 Electrical Characteristics: V<sub>s</sub> = 5 V

at  $V_{S+} = +5 \text{ V}$ ,  $V_{S-} = 0 \text{ V}$ ,  $V_{OUT} = 2 \text{ V}_{PP}$ ,  $R_F = 0 \Omega$ ,  $R_L = 1 \text{ k}\Omega$ , G = 1 V/V, input and output referenced to mid-supply.  $T_A = 25^{\circ}\text{C}$ , unless otherwise noted.

| PARAMETER                     | TEST CONDITIONS                                  | MIN | ТҮР  | МАХ  | UNIT    | TEST<br>LEVEL <sup>(1)</sup> |
|-------------------------------|--|-----|------|------|---------|------------------------------|
| AC PERFORMANCE                |  |     |      |      |         | •                            |
|                               | V <sub>OUT</sub> = 100 mV <sub>PP</sub> , G = 1  |     | 205  |      |         |                              |
| Small signal handwidth        | $V_{OUT} = 100 \text{ mV}_{PP}, \text{ G} = 2$   |     | 100  |      | • • • • | 0                            |
| Small-signal bandwidth        | $V_{OUT} = 100 \text{ mV}_{PP}, \text{ G} = 5$   |     | 28   |      | MHz     | С                            |
|                               | $V_{OUT} = 100 \text{ mV}_{PP}, \text{ G} = 10$  |     | 11.8 |      |         |                              |
| Gain-bandwidth product        | V <sub>OUT</sub> = 100 mV <sub>PP</sub> , G = 10 |     | 118  |      | MHz     | С                            |
| Large-signal bandwidth        | $V_{OUT} = 2 V_{PP}, G = 2$                      |     | 87   |      | MHz     | С                            |
| Bandwidth for 0.1-dB flatness | V <sub>OUT</sub> = 2 V <sub>PP</sub> , G = 2     |     | 29   |      | MHz     | С                            |
| Slew rate, rise               | V <sub>OUT</sub> = 2-V Step, G = 2               |     | 560  |      | V/µs    | С                            |
| Slew rate, fall               | V <sub>OUT</sub> = 2-V Step, G = 2               | 580 |      | V/µs | С       |                              |
| Rise time                     | V <sub>OUT</sub> = 2-V Step, G = 2               |     | 3    |      | ns      | С                            |
| Fall time                     | V <sub>OUT</sub> = 2-V Step, G = 2               |     | 3    |      | ns      | С                            |

(1) Test levels (all values set by characterization and simulation): (A) 100% tested at 25°C; over temperature limits by characterization and simulation. (B) Not tested in production; limits set by characterization and simulation. (C) Typical value only for information.



### Electrical Characteristics: V<sub>s</sub> = 5 V (continued)

at  $V_{S+}$  = +5 V,  $V_{S-}$  = 0 V,  $V_{OUT}$  = 2  $V_{PP}$ ,  $R_F$  = 0  $\Omega$ ,  $R_L$  = 1 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply.  $T_A$  = 25°C, unless otherwise noted.

| PARAMETER                                 | TEST CONDITIONS  | MIN   | ТҮР    | МАХ  | UNIT   | TEST<br>LEVEL <sup>(1)</sup> |
|---|--|-------|--------|------|--------|------------------------------|
| AC PERFORMANCE (continued)                |  |       |        |      |        |                              |
| Settling time to 1%, rise                 | $V_{OUT} = 2$ -V Step, G = 2   |       | 22     |      | ns     | С                            |
| Settling time to 1%, fall                 | V <sub>OUT</sub> = 2-V Step, G = 2   |       | 22     |      | ns     | С                            |
| Settling time to 0.1%, rise               | V <sub>OUT</sub> = 2-V Step, G = 2   |       | 30     |      | ns     | С                            |
| Settling time to 0.1%, fall               | V <sub>OUT</sub> = 2-V Step, G = 2   |       | 30     |      | ns     | С                            |
| Settling time to 0.01%, rise              | $V_{OUT} = 2$ -V Step, G = 2   |       | 40     |      | ns     | С                            |
| Settling time to 0.01%, fall              | $V_{OUT} = 2$ -V Step, G = 2   |       | 45     |      | ns     | С                            |
| Overshoot/Undershoot                      | V <sub>OUT</sub> = 2-V Step, G = 2   | 7     | .5%/5% |      |        | С                            |
|   | f = 10 kHz   |       | -133   |      |        |                              |
| Second-order harmonic distortion          | f = 100 kHz  |       | -120   |      | dBc    | С                            |
|   | f = 1 MHz  |       | -85    |      |        |                              |
|   | f = 10 kHz   |       | -140   |      |        |                              |
| Third-order harmonic distortion           | f = 100 kHz  |       | -130   |      | dBc    | С                            |
|   | f = 1 MHz  |       | -105   |      |        |                              |
| Second-order intermodulation distortion   | f = 1 MHz, 200 kHz Tone Spacing,<br>V <sub>OUT</sub> Envelope = 2 V <sub>PP</sub>                      |       | -79    |      | dBc    | С                            |
| Third-order intermodulation distortion    | f = 1 MHz, 200 kHz Tone Spacing, $V_{OUT}$ Envelope = 2 $V_{PP}$                                       |       | -91    |      | dBc    | С                            |
|   | $f = 1 \text{ kHz}, V_{OUT} = 1 V_{RMS},$  | 0.0   | 00013% |      |        | 0                            |
| Signal-to-noise ratio, SNR                | 22 kHz bandwidth   |       | -117.6 |      | dBc    | С                            |
|   |  | 0.0   | 00003% |      |        | •                            |
| Total harmonic distortion, THD            | $f = 1 \text{ kHz}, V_{OUT} = 1 V_{RMS}$   | -130  |        |      | dBc    | С                            |
| Input voltage noise                       | f = 100 KHz  |       | 4.6    |      | nV/√Hz | С                            |
| Voltage noise 1/f corner frequency        |  |       | 215    |      | Hz     | С                            |
| Input current noise                       | f > 1 MHz  |       | 0.75   |      | pA/√Hz | С                            |
| Current noise 1/f corner frequency        |  |       | 31.7   |      | kHz    | С                            |
| Overdrive recovery time, over/under       | Overdrive = 0.5 V  |       | 55/60  |      | ns     | С                            |
| Closed-loop output impedance              | f = 100 kHz  |       | 0.02   |      | Ω      | С                            |
| Channel to channel crosstalk (OPA2836)    | f = 10 kHz   |       | -120   |      | dB     | С                            |
| DC PERFORMANCE                            |  |       |        |      |        |                              |
| Open-loop voltage gain (A <sub>OL</sub> ) |  | 100   | 122    |      | dB     | А                            |
|   | T <sub>A</sub> = 25°C  | -400  | ±65    | 400  |        | А                            |
|   | $T_A = 0^{\circ}C$ to 70°C   | -685  |        | 685  |        |                              |
| Input referred offset voltage             | $T_A = -40^{\circ}C \text{ to } 85^{\circ}C$   | -765  |        | 765  | μV     | В                            |
|   | $T_A = -40^{\circ}C$ to 125°C  | -1080 |        | 1080 |        |                              |
|   | $T_A = 0^{\circ}C \text{ to } 70^{\circ}C$   | -6.3  | ±1.05  | 6.3  |        |                              |
| Input offset voltage drift <sup>(2)</sup> | $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$   | -6.1  | ±1     | 6.1  | µV/°C  | В                            |
|   | $T_{A} = -40^{\circ}C \text{ to } 125^{\circ}C$  | -6.8  | ±1.1   | 6.8  |        | -                            |
|   | $T_{A} = 25^{\circ}C$  | 300   | 650    | 1000 |        | A                            |
|   | $T_{A} = 0^{\circ}C \text{ to } 70^{\circ}C$   | 190   |        | 1400 |        |                              |
| Input bias current <sup>(3)</sup>         | $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$   | 130   |        | 1550 | nA     | В                            |
|   | $T_{A} = -40^{\circ} C \text{ to } 125^{\circ} C$<br>$T_{A} = -40^{\circ} C \text{ to } 125^{\circ} C$ | 120   |        | 1850 |        | D                            |
|   | $T_A = -40 \text{ C to } 123 \text{ C}$<br>$T_A = 0^{\circ}\text{C to } 70^{\circ}\text{C}$            | 120   | ±0.34  | ±2   |        |                              |
| Input bias current drift <sup>(2)</sup>   | $T_{A} = -40^{\circ}C \text{ to } 85^{\circ}C$   |       | ±0.34  | ±2   | nA/°C  | В                            |
|   |  |       |        |      | 10.4 0 | U U                          |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$   |       | ±0.38  | ±2.3 |        |                              |

(2) Input Offset Voltage Drift, Input Bias Current Drift, and Input Offset Current Drift are average values calculated by taking data at the end points, computing the difference, and dividing by the temperature range.

(3) Current is considered positive out of the pin.

#### OPA836, OPA2836 SLOS712I – JANUARY 2011 – REVISED OCTOBER 2016

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STRUMENTS

EXAS

# Electrical Characteristics: V<sub>s</sub> = 5 V (continued)

at  $V_{S+}$  = +5 V,  $V_{S-}$  = 0 V,  $V_{OUT}$  = 2  $V_{PP}$ ,  $R_F$  = 0  $\Omega$ ,  $R_L$  = 1 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply.  $T_A$  = 25°C, unless otherwise noted.

| PARAMETER                                 | TEST CONDITIONS   | MIN      | ТҮР             | МАХ  | UNIT     | TEST<br>LEVEL <sup>(1)</sup> |
|---|---|----------|-----------------|------|----------|------------------------------|
| DC PERFORMANCE (continued)                |   |          |                 |      |          |                              |
|   | $T_A = 25^{\circ}C$   |          | ±30             | ±180 |          | А                            |
| Input offset current                      | $T_A = 0^{\circ}C$ to $70^{\circ}C$   | ±30 ±200 |                 | nA   |          |                              |
| input onset current                       | $T_A = -40^{\circ}C$ to $85^{\circ}C$                                       |          | ±30             | ±215 | na       | В                            |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$                                      |          | ±30             | ±250 |          |                              |
|   | $T_A = 0^{\circ}C$ to $70^{\circ}C$   |          | ±80             | ±480 |          |                              |
| Input offset current drift <sup>(2)</sup> | $T_A = -40^{\circ}C$ to $85^{\circ}C$                                       |          | ±100            | ±600 | pA/°C    | В                            |
|   | $T_A = -40^{\circ}C$ to $125^{\circ}C$                                      |          | ±110            | ±660 |          |                              |
| INPUT                                     |   |          |                 |      |          |                              |
| Common-mode input range low               | $T_A = 25^{\circ}C$ ,<br>< 3-dB degradation in CMRR limit                   |          | -0.2            | 0    | V        | А                            |
|   | $T_A = -40$ °C to 125°C,<br>< 3-dB degradation in CMRR limit                |          | -0.2            | 0    | V        | В                            |
| Common-mode input range high              | $T_A = 25^{\circ}C$ ,<br>< 3-dB degradation in CMRR limit                   | 3.8      | 3.9             |      | V        | А                            |
|   | $T_A = -40^{\circ}C$ to 125°C,<br>< 3-dB degradation in CMRR limit          | 3.8      | 3.9             |      | V        | В                            |
| Input linear operating voltage range      | $T_A = 25^{\circ}C$ ,<br>< 6-dB degradation in THD                          |          | –0.3 to<br>4.05 |      | V        | С                            |
| Common-mode rejection ratio               |   | 94       | 116             |      | dB       | A                            |
| Input impedance common mode               |   |          | 200    1.2      |      | kΩ∥pF    | С                            |
| Input impedance differential mode OUTPUT  |   |          | 200    1        |      | kΩ    pF | С                            |
|   | $T_A = 25^{\circ}C, G = 5$  |          | 0.15            | 0.2  | V        | А                            |
| Output voltage low                        | $T_A = -40^{\circ}C$ to 125°C, G = 5  |          | 0.15            | 0.2  | V        | В                            |
|   | T <sub>A</sub> = 25°C, G = 5 4.75 4.8 V                                     | А        |                 |      |          |                              |
| Output voltage high                       | $T_A = -40^{\circ}C$ to 125°C, G = 5  | 4.75     | 4.8             |      | V        | В                            |
| Output saturation voltage, high/low       | $T_A = 25^{\circ}C, G = 5$  |          | 100/50          |      | mV       | С                            |
|   | T <sub>A</sub> = 25°C   | ±40      | ±50             |      | mA       | А                            |
| Output current drive                      | $T_A = -40^{\circ}C$ to $125^{\circ}C$                                      | ±40      | ±50             |      | mA       | В                            |
| GAIN SETTING RESISTORS (OPA836IRUN ONL    | .Y)   |          |                 |      |          |                              |
| Resistor FB1 to FB2                       | DC resistance   | 1584     | 1600            | 1616 | Ω        | А                            |
| Resistor FB2 to FB3                       | DC resistance   | 1188     | 1200            | 1212 | Ω        | А                            |
| Resistor FB3 to FB4                       | DC resistance   | 396      | 400             | 404  | Ω        | А                            |
| Resistor tolerance                        | DC resistance   | -1       |                 | 1%   |          | А                            |
| Resistor temperature coefficient          | DC resistance   |          | <10             |      | PPM      | С                            |
| POWER SUPPLY                              | <u> </u>  |          |                 |      |          |                              |
| Specified operating voltage               |   | 2.5      |                 | 5.5  | V        | В                            |
|   | T <sub>A</sub> = 25°C   | 0.8      | 1.0             | 1.2  | mA       | А                            |
| Quiescent operating current per amplifier | $T_A = -40^{\circ}C$ to 125°C   | 0.65     |                 | 1.5  | mA       | В                            |
| Power supply rejection (±PSRR)            |   | 94       | 108             |      | dB       | А                            |
| POWER DOWN                                | 1   |          |                 |      |          |                              |
| Enable voltage threshold                  | Specified "on" above V <sub>S</sub> + 2.1 V                                 |          |                 | 2.1  | V        | А                            |
| Disable voltage threshold                 | Specified "off" below V <sub>S</sub> + 0.7 V                                | 0.7      |                 |      | V        | А                            |
| Power-down pin bias current               | $\overline{PD} = 0.5 V$   |          | 20              | 500  | nA       | А                            |
| Power-down quiescent current              | PD = 0.5 V  |          | 0.5             | 1.5  | μA       | А                            |
| Turnon time delay                         | Time from $\overline{PD}$ = high to V <sub>OUT</sub> = 90% of final value   |          | 170             |      | ns       | C                            |
| Turnoff time delay                        | Time from $\overline{PD}$ = low to V <sub>OUT</sub> = 10% of original value |          | 35              |      | ns       | С                            |



### 7.8 Typical Characteristics

# 7.8.1 Typical Characteristics: $V_S = 2.7 V$

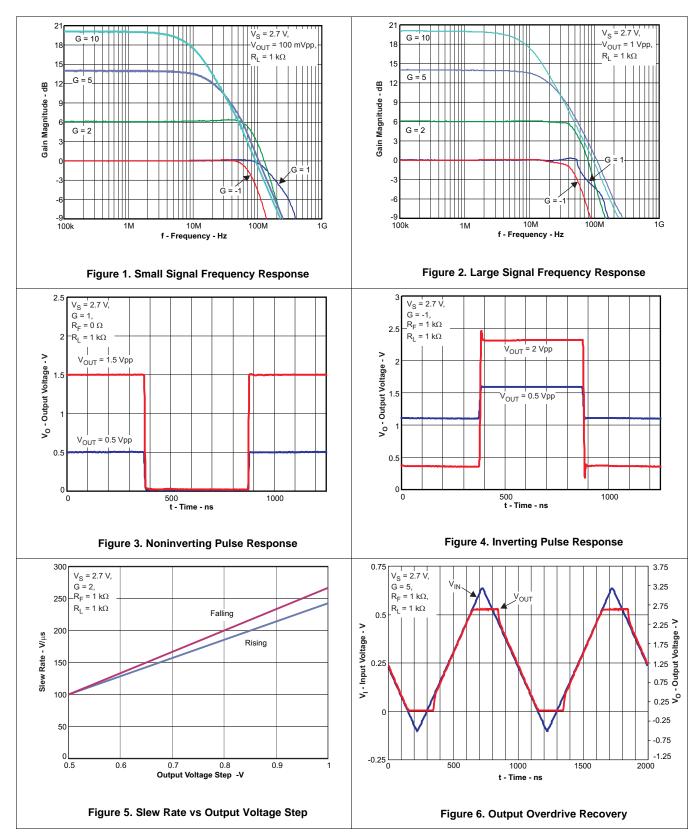
### Table 1. Table of Graphs

| FIGURE TITLE                              |                         | FIGURE LOCATION |
|---|-------------------------|-----------------|
| Small Signal Frequency Response           |                         | Figure 1        |
| Large Signal Frequency Response           |                         | Figure 2        |
| Noninverting Pulse Response               |                         | Figure 3        |
| Inverting Pulse Response                  |                         | Figure 4        |
| Slew Rate                                 | vs Output Voltage Step  | Figure 5        |
| Output Overdrive Recovery                 |                         | Figure 6        |
| Harmonic Distortion                       | vs Frequency            | Figure 7        |
| Harmonic Distortion                       | vs Load Resistance      | Figure 8        |
| Harmonic Distortion                       | vs Output Voltage       | Figure 9        |
| Harmonic Distortion                       | vs Gain                 | Figure 10       |
| Output Voltage Swing                      | vs Load Resistance      | Figure 11       |
| Output Saturation Voltage                 | vs Load Current         | Figure 12       |
| Output Impedance                          | vs Frequency            | Figure 13       |
| Frequency Response With Capacitive Load   |                         | Figure 14       |
| Series Output Resistor                    | vs Capacitive Load      | Figure 17       |
| Input Referred Noise                      | vs Frequency            | Figure 16       |
| Open Loop Gain                            | vs Frequency            | Figure 15       |
| Common Mode/Power Supply Rejection Ratios | vs Frequency            | Figure 18       |
| Crosstalk                                 | vs Frequency            | Figure 19       |
| Power Down Response                       |                         | Figure 20       |
| Input Offset Voltage                      |                         | Figure 23       |
| Input Offset Voltage                      | vs Free-Air Temperature | Figure 21       |
| Input Offset Voltage Drift                |                         | Figure 48       |
| Input Offset Current                      |                         | Figure 24       |
| Input Offset Current                      | vs Free-Air Temperature | Figure 25       |
| Input Offset Current Drift                |                         | Figure 26       |

OPA836, OPA2836

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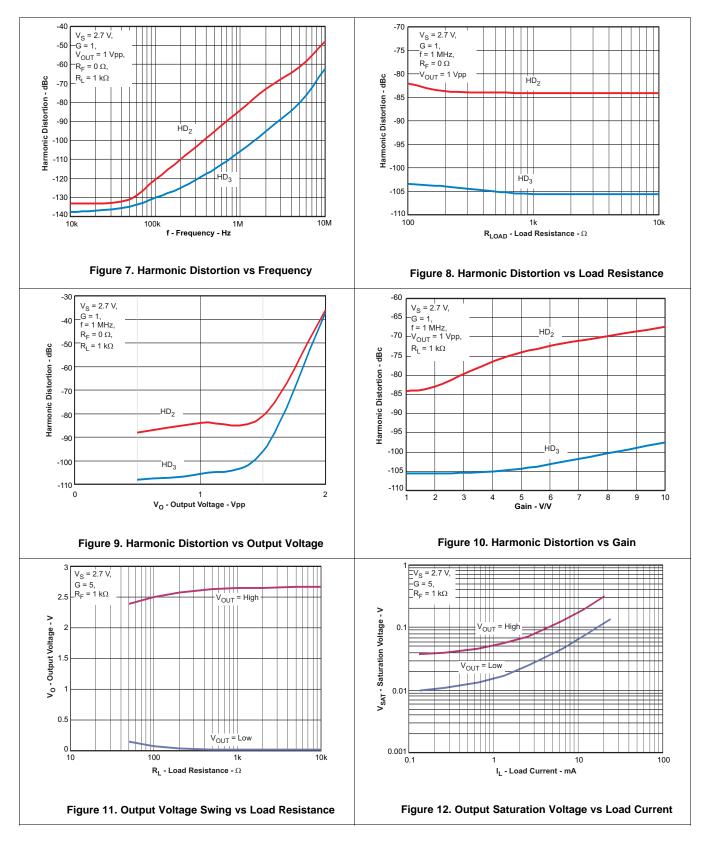
at V<sub>S+</sub> = +2.7 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 1 V<sub>pp</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply, V<sub>IN\_CM</sub> = mid-supply - 0.5 V. T<sub>A</sub> = 25°C, unless otherwise noted.



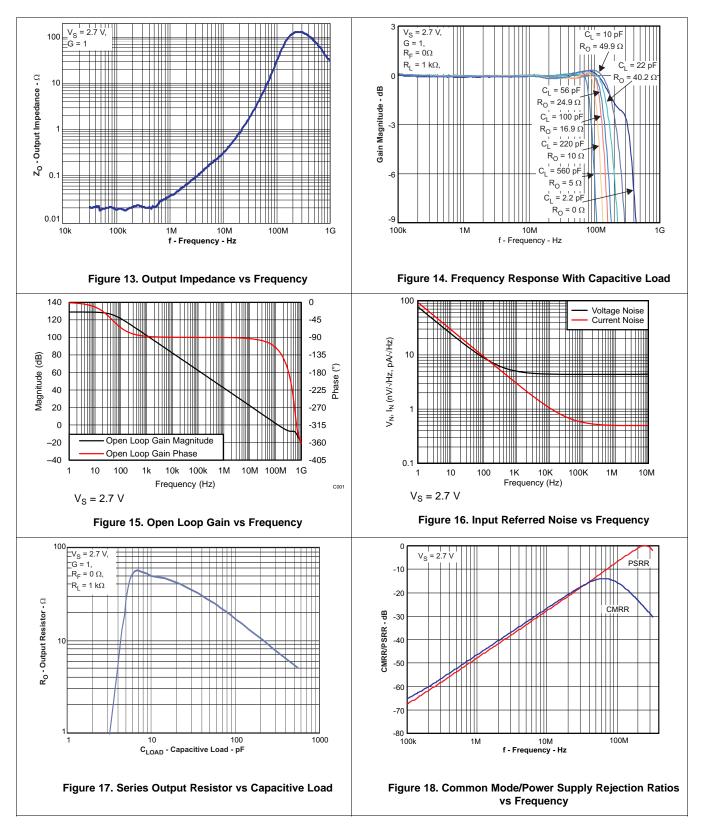
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at V<sub>S+</sub> = +2.7 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 1 V<sub>pp</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply, V<sub>IN\_CM</sub> = mid-supply - 0.5 V. T<sub>A</sub> = 25°C, unless otherwise noted.



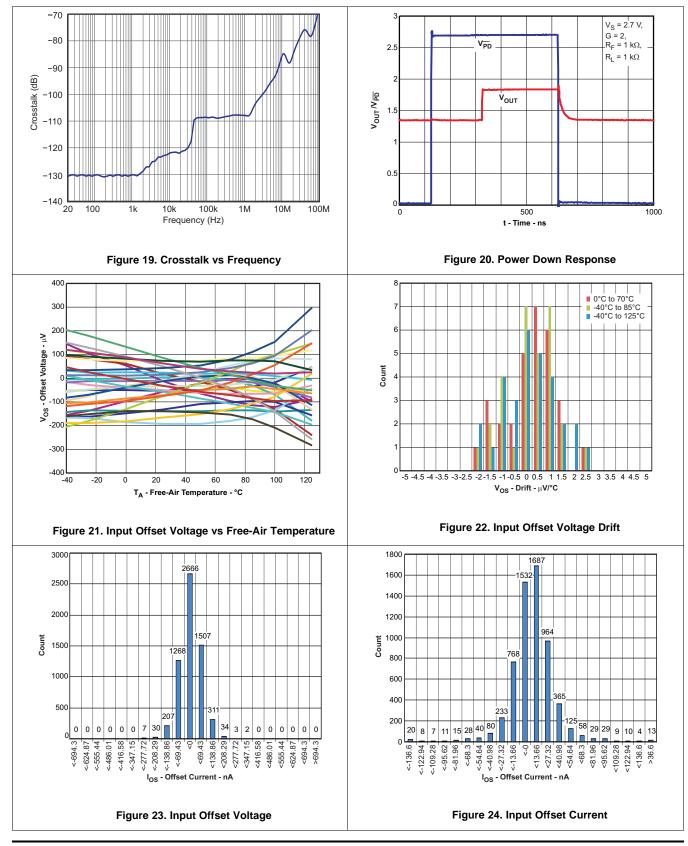
at V<sub>S+</sub> = +2.7 V, V<sub>S</sub> = 0 V, V<sub>OUT</sub> = 1 V<sub>pp</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply, V<sub>IN\_CM</sub> = mid-supply - 0.5 V. T<sub>A</sub> = 25°C, unless otherwise noted.



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at V<sub>S+</sub> = +2.7 V, V<sub>S</sub> = 0 V, V<sub>OUT</sub> = 1 V<sub>pp</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply, V<sub>IN\_CM</sub> = mid-supply - 0.5 V. T<sub>A</sub> = 25°C, unless otherwise noted.



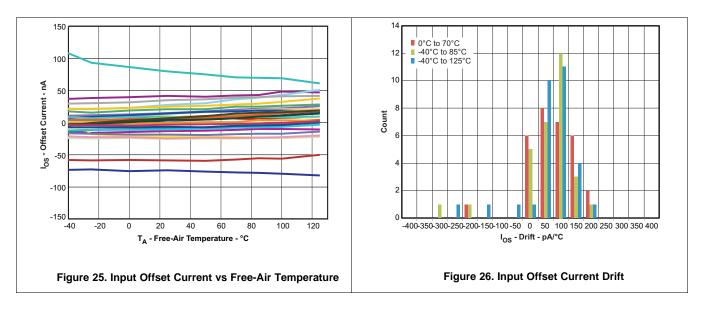
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STRUMENTS

EXAS

at V<sub>S+</sub> = +2.7 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 1 V<sub>pp</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 2 k $\Omega$ , G = 1 V/V, input and output referenced to mid-supply, V<sub>IN\_CM</sub> = mid-supply – 0.5 V. T<sub>A</sub> = 25°C, unless otherwise noted.





# 7.8.2 Typical Performance Graphs: $V_S = 5 V$

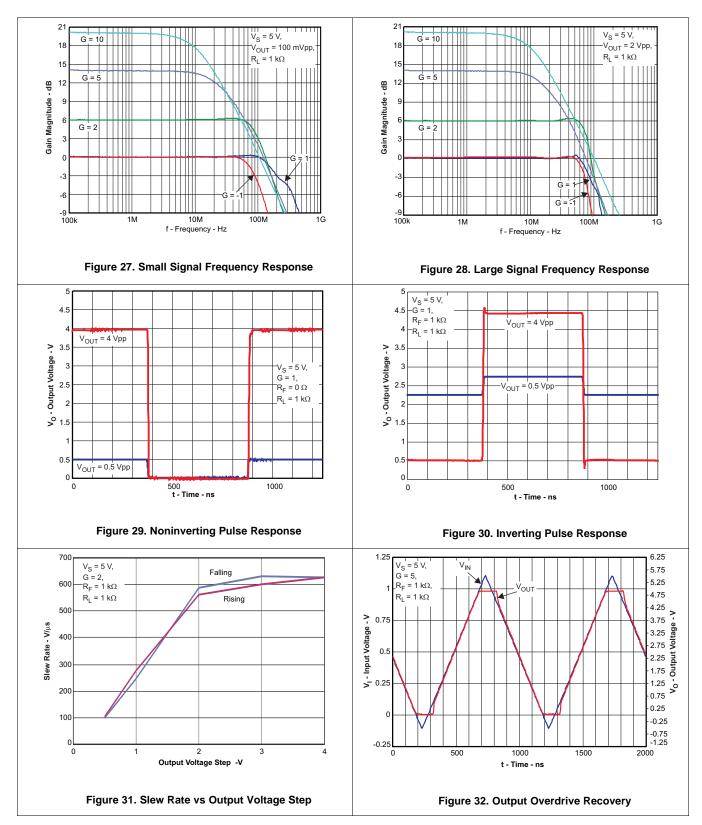
| FIGUR                                     | RETITLE                 | FIGURE LOCATION |
|---|-------------------------|-----------------|
| Small Signal Frequency Response           |                         | Figure 27       |
| Large Signal Frequency Response           |                         | Figure 28       |
| Noninverting Pulse Response               |                         | Figure 29       |
| Inverting Pulse Response                  |                         | Figure 30       |
| Slew Rate                                 | vs Output Voltage Step  | Figure 31       |
| Output Overdrive Recovery                 |                         | Figure 32       |
| Harmonic Distortion                       | vs Frequency            | Figure 33       |
| Harmonic Distortion                       | vs Load Resistance      | Figure 34       |
| Harmonic Distortion                       | vs Output Voltage       | Figure 35       |
| Harmonic Distortion                       | vs Gain                 | Figure 36       |
| Output Voltage Swing                      | vs Load Resistance      | Figure 37       |
| Output Saturation Voltage                 | vs Load Current         | Figure 38       |
| Output Impedance                          | vs Frequency            | Figure 39       |
| Frequency Response With Capacitive Load   |                         | Figure 40       |
| Series Output Resistor                    | vs Capacitive Load      | Figure 43       |
| Input Referred Noise                      | vs Frequency            | Figure 41       |
| Open Loop Gain                            | vs Frequency            | Figure 42       |
| Common Mode/Power Supply Rejection Ratios | vs Frequency            | Figure 44       |
| Crosstalk                                 | vs Frequency            | Figure 45       |
| Power Down Response                       |                         | Figure 46       |
| Input Offset Voltage                      |                         | Figure 49       |
| Input Offset Voltage                      | vs Free-Air Temperature | Figure 47       |
| Input Offset Voltage Drift                |                         | Figure 48       |
| Input Offset Current                      |                         | Figure 50       |
| Input Offset Current                      | vs Free-Air Temperature | Figure 51       |
| Input Offset Current Drift                |                         | Figure 52       |

### Table 2. Table of Graphs

**NSTRUMENTS** 

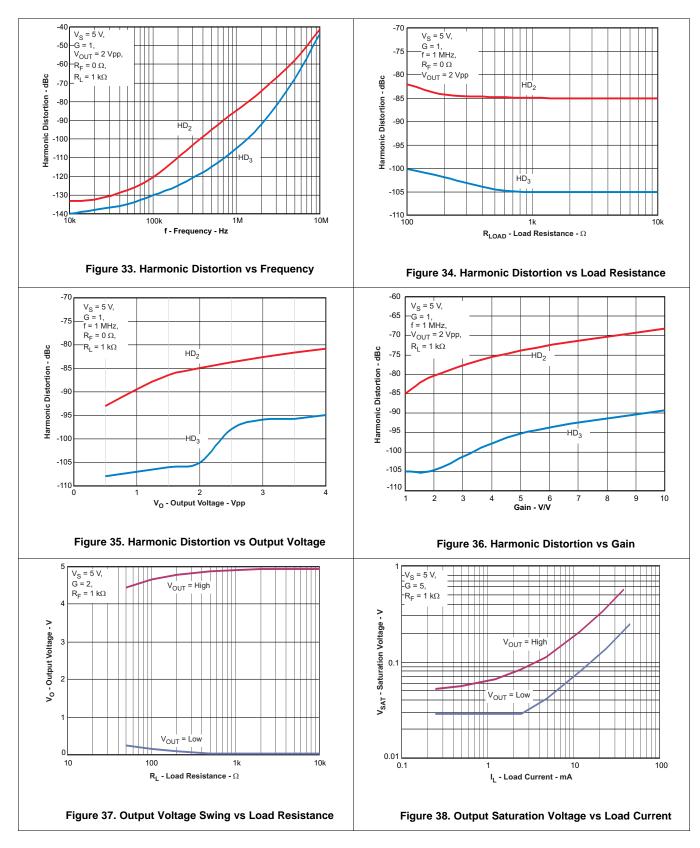
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at V<sub>S+</sub> = +5 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 2 V<sub>PP</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 1 k $\Omega$ , G = 1 V/V, input and output referenced to midsupply unless otherwise noted. T<sub>A</sub> = 25°C, unless otherwise noted.

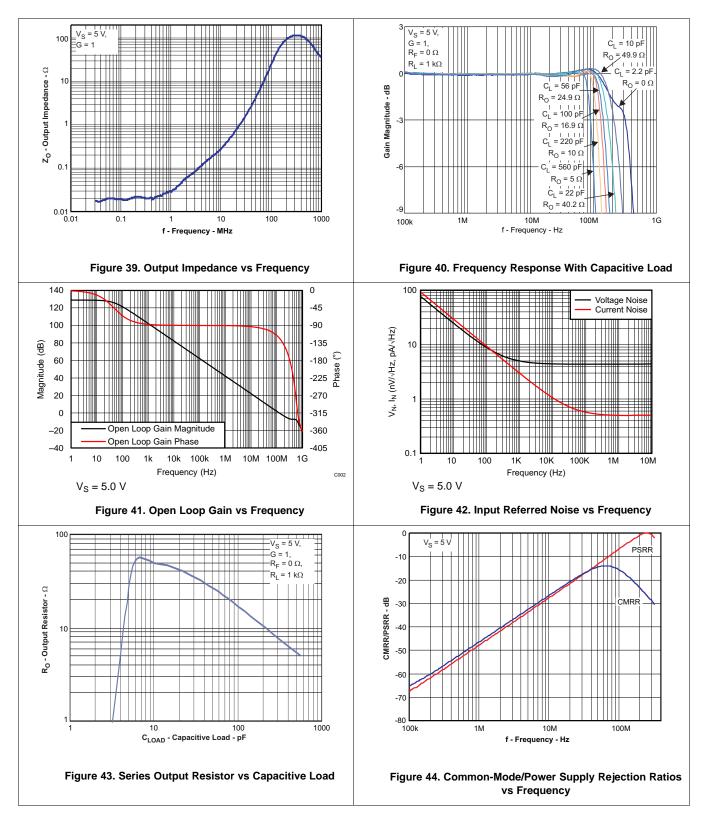




at V<sub>S+</sub> = +5 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 2 V<sub>PP</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 1 k $\Omega$ , G = 1 V/V, input and output referenced to midsupply unless otherwise noted. T<sub>A</sub> = 25°C, unless otherwise noted.



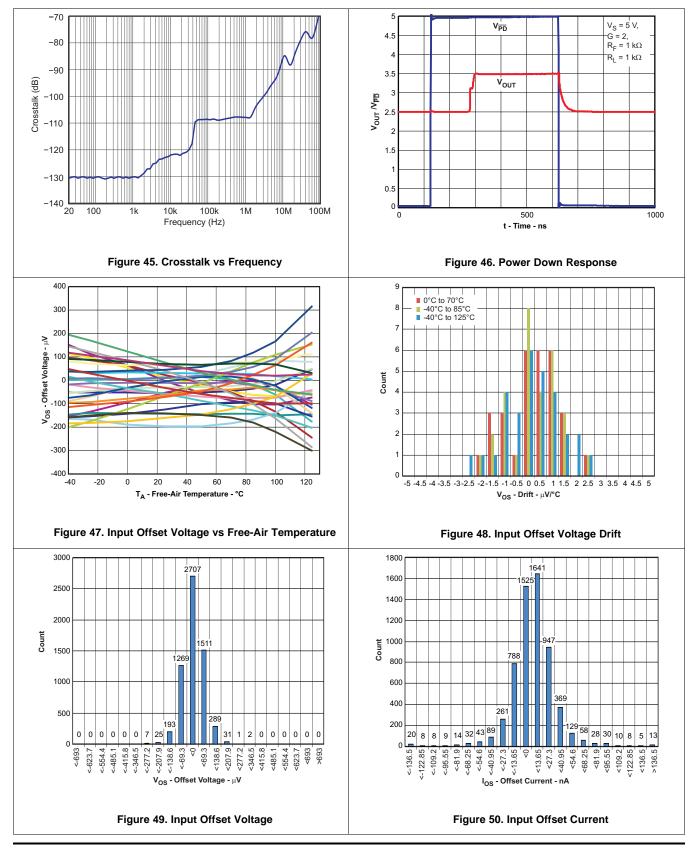
at V<sub>S+</sub> = +5 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 2 V<sub>PP</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 1 k $\Omega$ , G = 1 V/V, input and output referenced to midsupply unless otherwise noted. T<sub>A</sub> = 25°C, unless otherwise noted.







at V<sub>S+</sub> = +5 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 2 V<sub>PP</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 1 k $\Omega$ , G = 1 V/V, input and output referenced to midsupply unless otherwise noted. T<sub>A</sub> = 25°C, unless otherwise noted.

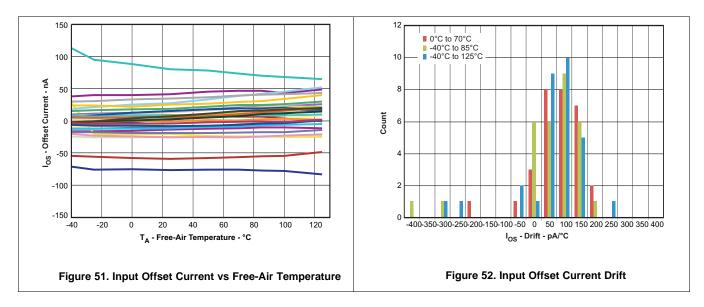


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TEXAS INSTRUMENTS

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at V<sub>S+</sub> = +5 V, V<sub>S-</sub> = 0 V, V<sub>OUT</sub> = 2 V<sub>PP</sub>, R<sub>F</sub> = 0  $\Omega$ , R<sub>L</sub> = 1 k $\Omega$ , G = 1 V/V, input and output referenced to midsupply unless otherwise noted. T<sub>A</sub> = 25°C, unless otherwise noted.



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## 8 Detailed Description

### 8.1 Overview

The OPAx836 family of bipolar-input operational amplifiers offers excellent bandwidth of 205 MHz with ultra-low THD of 0.00003% at 1 kHz. The OPAx836 device can swing to within 200 mV of the supply rails while driving a 1-k $\Omega$  load. The input common-mode of the amplifier can swing to 200 mV below the negative supply rail. This level of performance is achieved at 1 mA of quiescent current per amplifier channel.

### 8.2 Functional Block Diagrams

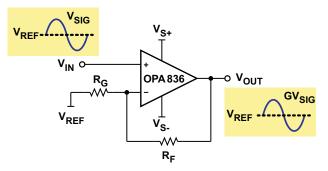


Figure 53. Noninverting Amplifier

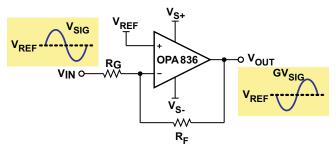


Figure 54. Inverting Amplifier

## 8.3 Feature Description

### 8.3.1 Input Common-Mode Voltage Range

When the primary design goal is a linear amplifier with high CMRR, it is important to not violate the input common-mode voltage range ( $V_{ICR}$ ) of an operational amplifier.

The common-mode input range specifications in the table data use CMRR to set the limit. The limits are selected to ensure CMRR will not degrade more than 3 dB below the CMRR limit if the input voltage is kept within the specified range. The limits cover all process variations and most parts will be better than specified. The typical specifications are from 0.2 V below the negative rail to 1.1 V below the positive rail.

Assuming the operational amplifier is in linear operation, the voltage difference between the input pins is small (ideally 0 V) and input common-mode voltage is analyzed at either input pin with the other input pin assumed to be at the same potential. The voltage at  $V_{IN+}$  is simple to evaluate. In noninverting configuration, Figure 53, the input signal,  $V_{IN}$ , must not violate the  $V_{ICR}$ . In inverting configuration, Figure 54, the reference voltage,  $V_{REF}$ , must be within the  $V_{ICR}$ .

The input voltage limits have fixed headroom to the power rails and track the power supply voltages. For one 5-V supply, the linear input voltage ranges from -0.2 V to 3.9 V and from -0.2 V to 1.6 V for a 2.7-V supply. The delta headroom from each power supply rail is the same in either case: -0.2 V and 1.1 V.

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### **Feature Description (continued)**

#### 8.3.2 Output Voltage Range

The OPA836 and OPA2836 devices are rail-to-rail output (RRO) operational amplifiers. Rail-to-rail output typically means the output voltage swings within a couple hundred millivolts of the supply rails. There are different ways to specify this: one is with the output still in linear operation and another is with the output saturated. Saturated output voltages are closer to the power supply rails than linear outputs, but the signal is not a linear representation of the input. Linear output is a better representation of how well a device performs when used as a linear amplifier. Saturation and linear operation limits are affected by the output current, where higher currents lead to more loss in the output transistors.

Figure 11 and Figure 37 show saturated voltage-swing limits versus output load resistance and Figure 12 and Figure 38 show the output saturation voltage versus load current. Given a light load, the output voltage limits have nearly constant headroom to the power rails and track the power supply voltages. For example, with a  $2 \cdot k\Omega$  load and single 5-V supply, the linear output voltage ranges from 0.15 V to 4.8 V, and ranges from 0.15 V to 2.5 V for a 2.7-V supply. The delta from each power supply rail is the same in either case: 0.15 V and 0.2 V.

With devices like the OPA836 and OPA2836, where the input range is lower than the output range, typically the input will limit the available signal swing only in noninverting gain of 1. Signal swing in noninverting configurations in gains > +1 and inverting configurations in any gain is typically limited by the output voltage limits of the operational amplifier.

#### 8.3.3 Power-Down Operation

The OPA836 and OPA2836 devices include a power-down mode. Under logic control, the amplifiers can switch from normal operation to a standby current of < 1.5  $\mu$ A. When the PD pin is connected high, the amplifier is active. Connecting PD pin low disables the amplifier and places the output in a high-impedance state. When the amplifier is configured as a unity-gain buffer, the output stage is in a high dc-impedance state. To protect the input stage of the amplifier, the devices use internal, back-to-back ESD diodes between the inverting and noninverting input pins. This configuration creates a parallel low-impedance path from the amplifier output to the noninverting pin when the differential voltage between the pins exceeds a diode voltage drop. When the op amp is configured in other gains, the feedback (RF) and gain (RG) resistor network forms a parallel load.

The PD pin must be actively driven high or low and must not be left floating. If the power-down mode is not used, PD must be tied to the positive supply rail.

 $\overline{PD}$  logic states are TTL with reference to the negative supply rail and V<sub>S</sub>. When the operational amplifier is powered from single-supply and ground and driven from logic devices with similar V<sub>DD</sub>, voltages to the operational amplifier do not require any special consideration. When the operational amplifier is powered from a split supply, with V<sub>S</sub> below ground, an open-collector type of interface with pullup resistor is more appropriate. Pullup resistor values must be lower than 100 k $\Omega$ . Additionally, the drive logic must be negated due to the inverting action of an open-collector gate.

### 8.3.4 Low-Power Applications and the Effects of Resistor Values on Bandwidth

The OPA836 and OPA2836 devices are designed for the nominal value of  $R_F$  to be 1 k $\Omega$  in gains other than +1. This gives excellent distortion performance, maximum bandwidth, best flatness, and best pulse response, but it also loads the amplifier. For example; in gain of 2 with  $R_F = R_G = 1 \ k\Omega$ ,  $R_G$  to ground, and  $V_{OUT} = 4 \ V$ , 2 mA of current will flow through the feedback path to ground. In gain of +1,  $R_G$  is open and no current will flow to ground. In low-power applications, it is desirable to reduce the current in the feedback by increasing the gain-setting resistors values. Using larger value gain resistors has two primary side effects (other than lower power) due to their interaction with parasitic circuit capacitance:

- Lowers the bandwidth
- Lowers the phase margin
  - This causes peaking in the frequency response
  - This also causes overshoot and ringing in the pulse response

Figure 55 shows the small-signal frequency response on OPA836EVM for noninverting gain of 2 with R<sub>F</sub> and R<sub>G</sub> equal to 1 k $\Omega$ , 10 k $\Omega$ , and 100 k $\Omega$ . The test was done with R<sub>L</sub> = 1 k $\Omega$ . Due to loading effects of R<sub>L</sub>, lower R<sub>L</sub> values may reduce the peaking, but higher values will not have a significant effect.



### Feature Description (continued)

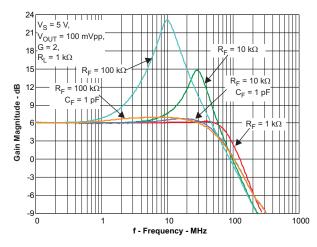


Figure 55. Frequency Response With Various Gain-Setting Resistor Values

As expected, larger value gain resistors cause lower bandwidth and peaking in the response (peaking in the frequency response is synonymous with overshoot and ringing in the pulse response). Adding 1-pF capacitors in parallel with  $R_F$  helps compensate the phase margin and restores flat frequency response. Figure 56 shows the test circuit.

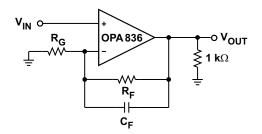


Figure 56. G = 2 Test Circuit for Various Gain-Setting Resistor Values

### 8.3.5 Driving Capacitive Loads

The OPA836 and OPA2836 devices can drive up to a nominal capacitive load of 2.2 pF on the output with no special consideration. When driving capacitive loads greater than 2.2 pF, TI recommends using a small resister ( $R_0$ ) in series with the output as close to the device as possible. Without  $R_0$ , capacitance on the output interacts with the output impedance of the amplifier causing phase shift in the loop gain of the amplifier that will reduce the phase margin. This will cause peaking in the frequency response and overshoot and ringing in the pulse response. Interaction with other parasitic elements may lead to instability or oscillation. Inserting  $R_0$  will isolate the phase shift from the feedback path and restore the phase margin; however,  $R_0$  can limit the bandwidth slightly.

Figure 57 shows the test circuit and Figure 43 shows the recommended values of  $R_0$  versus capacitive loads,  $C_L$ . See Figure 40 for the frequency response with various values.

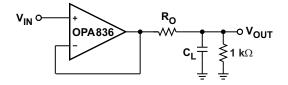


Figure 57. R<sub>o</sub> versus C<sub>L</sub> Test Circuit



### 8.4 Device Functional Modes

### 8.4.1 Split-Supply Operation (±1.25 V to ±2.75 V)

To facilitate testing with common lab equipment, the OPA836 EVM (see *OPA835DBV, OPA836DBV EVM*, SLOU314) is built to allow for split-supply operation. This configuration eases lab testing because the mid-point between the power rails is ground, and most signal generators, network analyzers, oscilloscopes, spectrum analyzers and other lab equipment have inputs and outputs with a ground reference.

Figure 58 shows a simple noninverting configuration analogous to Figure 53 with  $\pm 2.5$ -V supply and V<sub>REF</sub> equal to ground. The input and output will swing symmetrically around ground. For ease of use, split supplies are preferred in systems where signals swing around ground.

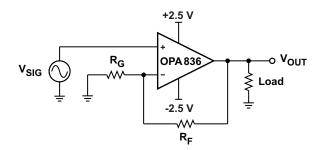


Figure 58. Split-Supply Operation

### 8.4.2 Single-Supply Operation (2.5 V to 5.5 V)

Often, newer systems use a single power supply to improve efficiency and reduce the cost of the power supply. The OPA836 and OPA2836 devices are designed for use with a single supply with no change in performance compared to a split supply, as long as the input and output are biased within the linear operation of the device.

To change the circuit from split supply to single supply, level shift of all voltages by half the difference between the power supply rails. For example, changing from  $\pm 2.5$ -V split supply to 5-V single supply is shown in Figure 59.

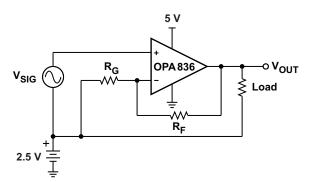


Figure 59. Single-Supply Concept

A practical circuit will have an amplifier or other circuit providing the bias voltage for the input, and the output of this amplifier stage provides the bias for the next stage.

Figure 60 shows a typical noninverting amplifiercircuit. With 5-V single-supply, a mid-supply reference generator is needed to bias the negative side through  $R_G$ . To cancel the voltage offset that would otherwise be caused by the input bias currents,  $R_1$  is selected to be equal to  $R_F$  in parallel with  $R_G$ . For example, if gain of 2 is required and  $R_F = 1 \ k\Omega$ , select  $R_G = 1 \ k\Omega$  to set the gain and  $R_1 = 499 \ \Omega$  for bias-current cancellation. The value for C depends on the reference; TI recommends a value of at least 0.1 µF to limit noise.



### **Device Functional Modes (continued)**

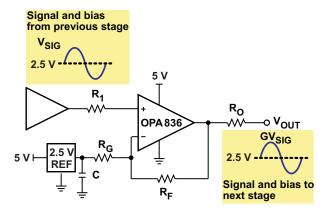


Figure 60. Noninverting Single Supply With Reference

Figure 61 shows a similar noninverting single-supply scenario with the reference generator replaced by the Thevenin equivalent using resistors and the positive supply.  $R_G'$  and  $R_G''$  form a resistor divider from the 5-V supply and are used to bias the negative side with their parallel sum equal to the equivalent  $R_G$  to set the gain. To cancel the voltage offset that would otherwise be caused by the input bias currents,  $R_1$  is selected to be equal to  $R_F$  in parallel with  $R_G''$  in parallel with  $R_G'' (R_1 = R_F || R_G' || R_G'')$ . For example, if gain of 2 is required and  $R_F = 1 k\Omega$ , selecting  $R_G' = R_G'' = 2 k\Omega$  gives equivalent parallel sum of 1 k $\Omega$ , sets the gain to 2, and references the input to mid supply (2.5 V).  $R_1$  is then set to 499  $\Omega$  for bias-current cancellation. The resistor divider costs less than the 2.5 V reference in Figure 60 but may increase the current from the 5-V supply.

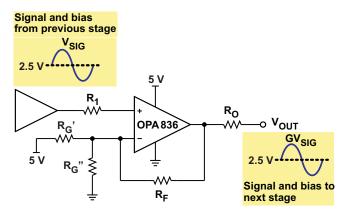


Figure 61. Noninverting Single Supply With Resistors

Figure 62 shows a typical inverting amplifier situation. With 5-V single supply, a mid-supply reference generator is needed to bias the positive side through R<sub>1</sub>. To cancel the voltage offset that would otherwise be caused by the input bias currents, R<sub>1</sub> is selected to be equal to R<sub>F</sub> in parallel with R<sub>G</sub>. For example if gain of -2 is required and R<sub>F</sub> = 1 k $\Omega$ , select R<sub>G</sub> = 499  $\Omega$  to set the gain and R<sub>1</sub> = 332  $\Omega$  for bias-current cancellation. The value for C is dependent on the reference, but TI recommends a value of at least 0.1 µF to limit noise into the operational amplifier.



### **Device Functional Modes (continued)**

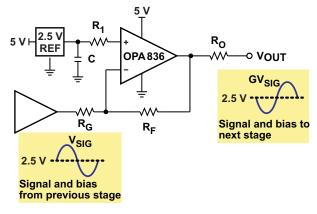


Figure 62. Inverting Single Supply With Reference

Figure 63 shows a similar inverting single-supply scenario with the reference generator replaced by the Thevenin equivalent using resistors and the positive supply.  $R_1$  and  $R_2$  form a resistor divider from the 5-V supply and are used to bias the positive side. To cancel the voltage offset that would otherwise be caused by the input bias currents, set the parallel sum of  $R_1$  and  $R_2$  equal to the parallel sum of  $R_F$  and  $R_G$ . C must be added to limit coupling of noise into the positive input. For example if gain of -2 is required and  $R_F = 1 \ k\Omega$ , select  $R_G = 499 \ \Omega$  to set the gain.  $R_1 = R_2 = 665 \ \Omega$  for mid-supply voltage bias and for operational amplifier input bias-current cancellation. A good value for C is 0.1  $\mu$ F. The resistor divider costs less than the 2.5-V reference in Figure 62 but may increase the current from the 5-V supply.

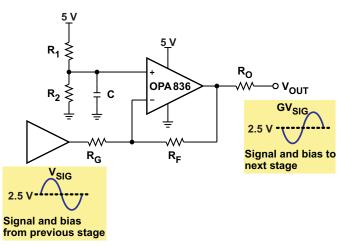


Figure 63. Inverting Single Supply With Resistors



#### Application and Implementation 9

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

#### 9.1.1 Noninverting Amplifier

The OPA836 and OPA2836 devices can be used as noninverting amplifiers with signal input to the noninverting input,  $V_{IN+}$ . A basic block diagram of the circuit is shown in Figure 53.

If  $V_{IN} = V_{REF} + V_{SIG}$ , then the output of the amplifier may be calculated according to Equation 1.

 $G = 1 + \frac{R_F}{R_F}$ 

$$V_{OUT} = V_{SIG} \left( 1 + \frac{R_F}{R_G} \right) + V_{REF}$$
(1)

The signal gain of the circuit is set by 
$$R_{G}$$
 , and  $V_{REF}$  provides a reference around which the input and putput signals swing. Output signals are in-phase with the input signals.

The OPA836 and OPA2836 devices are designed for the nominal value of  $R_F$  to be 1 k $\Omega$  in gains other than +1. This gives excellent distortion performance, maximum bandwidth, best flatness, and best pulse response. R<sub>F</sub> = 1 kΩ must be used as a default unless other design goals require changing to other values. All test circuits used to collect data for this data sheet had  $R_F = 1 \ k\Omega$  for all gains other than +1. Gain of +1 is a special case where  $R_F$  is shorted and R<sub>G</sub> is left open.

### 9.1.2 Inverting Amplifier

The OPA836 and OPA2836 devices can be used as inverting amplifiers with signal input to the inverting input,  $V_{IN-}$ , through the gain setting resistor R<sub>G</sub>. A basic block diagram of the circuit is shown in Figure 54.

If  $V_{IN} = V_{REF} + V_{SIG}$ , then the output of the amplifier may be calculated according to Equation 2.

$$V_{OUT} = V_{SIG} \left( \frac{-R_F}{R_G} \right) + V_{REF}$$
(2)

$$G = \frac{-R_F}{R_G}$$
The signal gain of the circuit is set by G =  $\frac{-R_F}{R_G}$ , and V<sub>REF</sub> provides a reference point around which the input and output signals swing. Output signals are 180° out-of-phase with the input signals. The nominal value of R<sub>F</sub> must be 1 k $\Omega$  for inverting gains.

#### 9.1.3 Instrumentation Amplifier

r

Figure 64 is an instrumentation amplifier that combines the high input impedance of the differential-to-differential amplifier circuit and the common-mode rejection of the differential-to-single-ended amplifier circuit. This circuit is often used in applications where high input impedance is required (such as taps from a differential line) or in cases where the signal source has a high output impedance.

If  $V_{IN+} = V_{CM} + V_{SIG+}$  and  $V_{IN-} = V_{CM} + V_{SIG-}$ , then the output of the amplifier may be calculated according to Equation 3.

$$V_{OUT} = \left(V_{IN+} - V_{IN-}\right) \times \left(1 + \frac{2R_{F1}}{R_{G1}}\right) \left(\frac{R_{F2}}{R_{G2}}\right) + V_{REF}$$

(3)

(4)

### **Application Information (continued)**

$$G = \left(1 + \frac{2R_{F1}}{R_{G1}}\right) \left(\frac{R_{F2}}{R_{G2}}\right). V_{CM} \text{ is rejected, and } V_{REF} \text{ provides a level shift}$$

The signal gain of the circuit is set by  $({}^{K_{G1}})({}^{K_{G2}})$ . V<sub>CM</sub> is rejected, and V<sub>REF</sub> provides a level shift around which the output signal swings. The single-ended output signal is in-phase with the differential input signal.

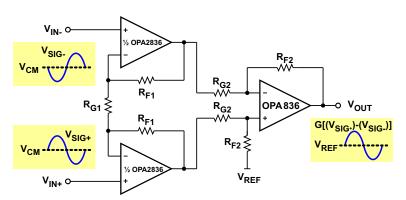


Figure 64. Instrumentation Amplifier

Integrated solutions are available, but the OPA836 device provides a much lower-power, high-frequency solution. For best CMRR performance, resistors must be matched. A good guideline to follow is CMRR  $\approx$  the resistor tolerance; so, 0.1% tolerance will provide approximately 60-dB CMRR.

### 9.1.4 Attenuators

The noninverting circuit of Figure 53 has minimum gain of 1. To implement attenuation, a resistor divider can be placed in series with the positive input, and the amplifier set for gain of 1 by shorting  $V_{OUT}$  to  $V_{IN-}$  and removing  $R_G$ . Because the operational amplifier input is high impedance, the resistor divider sets the attenuation.

The inverting circuit of Figure 54 can be used as an attenuator by making  $R_G$  larger than  $R_F$ . The attenuation is the resistor ratio. For example, a 10:1 attenuator can be implemented with  $R_F = 1 \ k\Omega$  and  $R_G = 10 \ k\Omega$ .

### 9.1.5 Single-Ended-to-Differential Amplifier

Figure 65 shows an amplifier circuit that is used to convert single-ended signals to differential, and provides gain and level shifting. This circuit can be used for converting signals to differential in applications like line drivers for Cat5 cabling or driving differential-input SAR and  $\Delta\Sigma$  ADCs.

With  $V_{IN} = V_{REF} + V_{SIG}$ , the output of the amplifier may be calculated according to Equation 4.

$$V_{OUT+} = G \times V_{IN} + V_{REF}$$
 and  $V_{OUT-} = -G \times V_{IN} + V_{REF}$  Where:  $G = 1 + \frac{R_F}{R_G}$ 

The differential-signal gain of the circuit is  $2 \times G$ , and  $V_{REF}$  provides a reference around which the output signal swings. The differential output signal is in-phase with the single-ended input signal.

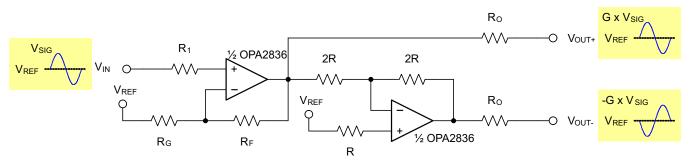


Figure 65. Single Ended to Differential Amplifier



### **Application Information (continued)**

Line termination on the output can be accomplished with resistors R<sub>0</sub>. The differential impedance seen from the line will be  $2 \times R_0$ . For example, if 100- $\Omega$  Cat5 cable is used with double termination, the amplifier is typically set for a differential gain of 2 V/V (6 dB) with R<sub>F</sub> = 0  $\Omega$  (short), R<sub>G</sub> = open, 2R = 1 k $\Omega$ , R1 = 0  $\Omega$ , R = 499  $\Omega$  to balance the input bias currents, and R<sub>0</sub> = 49.9  $\Omega$  for output line termination. This configuration is shown in Figure 66.

For driving a differential-input ADC the situation is similar, but the output resistors, R<sub>O</sub> are selected with a capacitor across the ADC input for optimum filtering and settling-time performance.

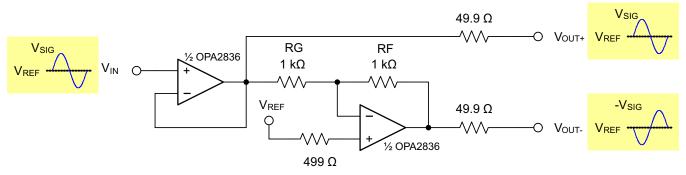


Figure 66. Cat5 Line Driver With Gain = 2 V/V (6 dB)

#### 9.1.6 Differential-to-Signal-Ended Amplifier

Figure 67 shows a differential amplifier that is used to convert differential signals to single-ended and provides gain (or attenuation) and level shifting. This circuit can be used in applications like a line receiver for converting a differential signal from a Cat5 cable to a single-ended signal.

If  $V_{IN+} = V_{CM} + V_{SIG+}$  and  $V_{IN-} = V_{CM} + V_{SIG-}$ , then the output of the amplifier may be calculated according to Equation 5.

$$V_{OUT} = (V_{IN+} - V_{IN-}) \times \left(\frac{R_F}{R_G}\right) + V_{REF}$$
(5)

The signal gain of the circuit is  $R_G^{-}$ ,  $V_{CM}$  is rejected, and  $V_{REF}$  provides a level shift around which the output signal swings. The single ended output signal is in-phase with the differential input signal.

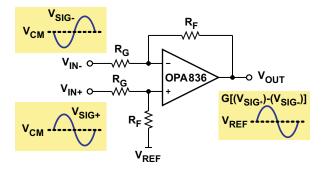


Figure 67. Differential to Single-Ended Amplifier

Line termination can be accomplished by adding a shunt resistor across the VIN+ and VIN- inputs. The differential impedance is the shunt resistance in parallel with the input impedance of the amplifier circuit, which is usually much higher. For low gain and low line impedance, the resistor value to add is approximately the impedance of the line. For example if 100- $\Omega$  Cat5 cable is used with a gain of 1 amplifier and R<sub>F</sub> = R<sub>G</sub> = 1 k $\Omega$ , adding a 100- $\Omega$  shunt across the input will give a differential impedance of 98  $\Omega$ , which is adequate for most applications.

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### **Application Information (continued)**

For best CMRR performance, resistors must be matched. Assuming CMRR  $\approx$  the resistor tolerance, a 0.1% tolerance will provide about 60-dB CMRR.

### 9.1.7 Differential-to-Differential Amplifier

Figure 68 shows a differential amplifier that is used to amplify differential signals. This circuit has high input impedance and is used in differential line driver applications where the signal source is a high-impedance driver (for example, a differential DAC) that must drive a line.

If  $V_{IN\pm} = V_{CM} + V_{SIG\pm}$ , then the output of the amplifier may be calculated according to Equation 6.

$$V_{OUT \pm} = V_{IN\pm} \times \left(1 + \frac{2R_F}{R_G}\right) + V_{CM}$$

$$G = 1 + \frac{2R_F}{R_G}$$
(6)

The signal gain of the circuit is set by  $R_G$ , and  $V_{CM}$  passes with unity gain. The amplifier in essence combines two noninverting amplifiers into one differential amplifier that shares the R<sub>G</sub> resistor, which makes R<sub>G</sub> effectively half its value when calculating the gain. The output signals are in-phase with the input signals.

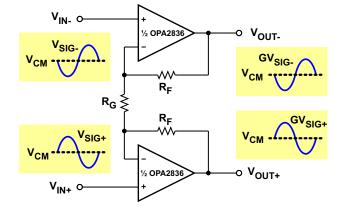
Figure 68. Differential to Differential Amplifier

### 9.1.8 Gain Setting With OPA836 RUN Integrated Resistors

The OPA836 RUN package option includes integrated gain-setting resistors for smallest possible footprint on a printed circuit board ( $\approx$  2.00 mm × 2.00 mm). By adding circuit traces on the PCB, gains of +1, -1, -1.33, +2, +2.33, -3, +4, -4, +5, -5.33, +6.33, -7, +8 and inverting attenuations of -0.1429, -0.1875, -0.25, -0.33, -0.75 can be achieved.

Figure 69 shows a simplified view of how the OPA836IRUN integrated gain-setting network is implemented. Table 3 lists the required pin connections for various noninverting and inverting gains (reference Figure 53 and Figure 54). Table 4 shows the required pin connections for various attenuations using the inverting-amplifier architecture (reference Figure 54). Due to ESD protection devices being used on all pins, the absolute maximum and minimum input-voltage range,  $V_{S-} - 0.7$  V to  $V_{S+} + 0.7$  V, applies to the gain-setting resistors, so attenuation of large input voltages requires external resistors to implement.

The gain-setting resistors are laser trimmed to 1% tolerance with nominal values of 1.6 k $\Omega$ , 1.2 k $\Omega$ , and 400  $\Omega$ . The gain-setting resistors have excellent temperature coefficients, and gain drift is superior to the drift with external gain-setting resistors. The 500- $\Omega$  and 1.5-pF capacitor in parallel with the 1.6-k $\Omega$  gain-setting resistor provide compensation for best stability and pulse response.





### **Application Information (continued)**

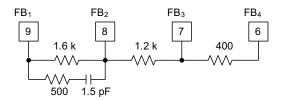


Figure 69. OPA836IRUN Gain-Setting Network

| NONINVERTING GAIN<br>(Figure 53) | INVERTING GAIN<br>(Figure 54) | SHORT PINS | SHORT PINS  | SHORT PINS | SHORT PINS |
|----------------------------------|-------------------------------|------------|-------------|------------|------------|
| 1 V/V (0 dB)                     | —                             | 1 to 9     |             |            | —          |
| 2 V/V (6.02 dB)                  | -1 V/V (0 dB)                 | 1 to 9     | 2 to 8      | 6 to GND   | —          |
| 2.33 V/V (7.36 dB)               | –1.33 V/V (2.5 dB)            | 1 to 9     | 2 to 8      | 7 to GND   | —          |
| 4 V/V (12.04 dB)                 | –3 V/V (9.54 dB)              | 1 to 8     | 2 to 7      | 6 to GND   | —          |
| 5 V/V (13.98 dB)                 | –4 V/V (12.04 dB)             | 1 to 9     | 2 to 7 or 8 | 7 to 8     | 6 to GND   |
| 6.33 V/V (16.03 dB)              | –5.33 V/V (14.54 dB)          | 1 to 9     | 2 to 6 or 8 | 6 to 8     | 7 to GND   |
| 8 V/V (18.06 dB)                 | -7 V/V (16.90 dB)             | 1 to 9     | 2 to 7      | 6 to GND   |            |

### Table 3. Gain Settings

#### Table 4. Attenuator Settings

| INVERTING GAIN<br>(Figure 54) | SHORT PINS | SHORT PINS  | SHORT PINS | SHORT PINS |
|-------------------------------|------------|-------------|------------|------------|
| –0.75 V/V (–2.5 dB)           | 1 to 7     | 2 to 8      | 9 to GND   | _          |
| -0.333 V/V (-9.54 dB)         | 1 to 6     | 2 to 7      | 8 to GND   | —          |
| -0.25 V/V (-12.04 dB)         | 1 to 6     | 2 to 7 or 8 | 7 to 8     | 9 to GND   |
| –0.1875 V/V (–14.54 dB)       | 1 to 7     | 2 to 6 or 8 | 6 to 8     | 9 to GND   |
| -0.1429 V/V (-16.90 dB)       | 1 to 6     | 2 to 7      | 9 to GND   | —          |

### 9.1.9 Pulse Application With Single-Supply

For pulsed applications, where the signal is at ground and pulses to a positive or negative voltage, the circuit bias-voltage considerations differ from those in an application with a signal that swings symmetrical about a reference point. Figure 70 shows a circuit where the signal is at ground (0 V) and pulses to a positive value.

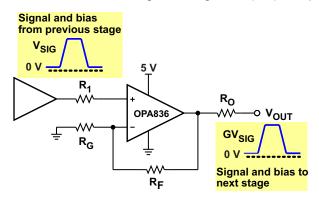


Figure 70. Noninverting Single Supply With Pulse

**NSTRUMENTS** 

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If the input signal pulses negative from ground, an inverting amplifier is more appropriate as shown in Figure 71. A key consideration in noninverting and inverting cases is that the input and output voltages are kept within the limits of the amplifier. Because the  $V_{ICR}$  of the OPA836 device includes the negative supply rail, the OPA836 operational amplifier is well-suited to this application.

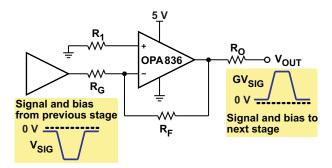


Figure 71. Inverting Single Supply With Pulse

### 9.1.10 ADC Driver Performance

The OPA836 device provides excellent performance when driving high-performance delta-sigma ( $\Delta\Sigma$ ) and successive-approximation-register (SAR) ADCs in low-power audio and industrial applications.

To show achievable performance, the OPA836 device is tested as the drive amplifier for the ADS8326. The ADS8326 is a 16-bit, micro power, SAR ADC with pseudodifferential inputs and sample rates up to 250 kSPS. The device offers excellent noise and distortion performance in a small 8-pin SOIC or VSSOP (MSOP) package. Low power and small size make the ADS8326 and OPA836 devices an ideal solution for portable and battery-operated systems, remote data-acquisition modules, simultaneous multichannel systems, and isolated data acquisition.

With the circuit shown in Figure 72 to test the performance, Figure 73 shows the FFT plot with a 10-kHz input signal . The tabulated AC analysis is in Table 5.

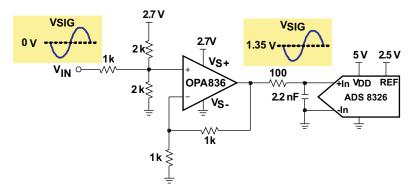


Figure 72. OPA836 and ADS8326 Test Circuit



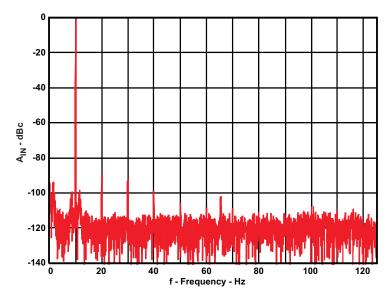


Figure 73. ADS8326 and OPA836 10-kHz FFT

#### Table 5. AC Analysis

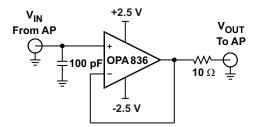
| TONE (Hz) | SIGNAL (dBFS) | SNR (dBc) | THD (dBc) | SINAD (dBc) | SFDR (dBc) |  |
|-----------|---------------|-----------|-----------|-------------|------------|--|
| 10k       | -0.85         | 83.3      | -86.6     | 81.65       | 88.9       |  |

### 9.2 Typical Applications

#### 9.2.1 Audio Frequency Performance

The OPA836 and OPA2836 devices provide excellent audio performance with low quiescent power. To show performance in the audio band, an audio analyzer from Audio Precision (2700 series) tests THD+N and FFT at 1  $V_{\text{RMS}}$  output voltage.

Figure 74 shows the circuit used for the audio-frequency performance test.



The 100-pF capacitor to ground on the input helped to decouple noise pick up in the lab and improved noise performance.

#### Figure 74. OPA836 Audio Precision Analyzer Test Circuit



## **Typical Applications (continued)**

#### 9.2.1.1 Design Requirements

Design a low distortion, single-ended input to single-ended output audio amplifier using the OPA836 device. The 2700-series audio analyzer from Audio Precision is used as the signal source and also as the measurement system.

|                           | 5                    | •                     |                     |
|---------------------------|----------------------|-----------------------|---------------------|
| CONFIGURATION             | INPUT<br>EXCITATION  | PERFORMANCE<br>TARGET | R <sub>Load</sub>   |
| OPA836 Unity Gain Config. | 1 KHz Tone Frequency | >110 dBc SFDR         | 300 Ω and<br>100 kΩ |

#### **Table 6. Design Requirements**

#### 9.2.1.2 Detailed Design Procedure

The OPA836 device is tested in this application in a unity-gain buffer configuration. A buffer configuration is selected for maximum loop gain of the amplifier circuit. At higher closed-loop gains, the loop gain of the circuit reduces, which increases the harmonic distortion. The relationship between distortion and closed-loop gain at a fixed input frequency is shown in Figure 36 in Typical Performance Graphs:  $V_S = 5$  V. The test was performed under using resistive loads of 300  $\Omega$  and 100 K $\Omega$ . Figure 34 shows the distortion performance of the amplifier versus the resistive load. Output loading, output swing, and closed-loop gain play a key role in determining the distortion performance of the amplifier.

#### NOTE

The 100-pF capacitor to ground on the input helped to decouple noise pickup in the lab and improved noise performance.

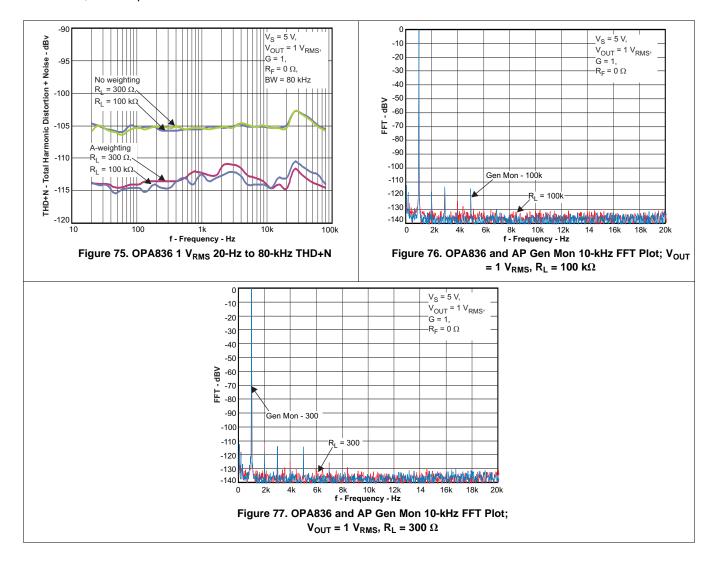
The Audio Precision was configured as a single-ended output in this application circuit. In applications where a differential output is available, the OPA836 device can be configured as a differential-to-single-ended amplifier as shown in Figure 67. Power-supply bypassing is critical to reject noise from the power supplies. A 2.2- $\mu$ F supply decoupling capacitor must be placed within 2 inches of the device and can be shared with other operational amplifiers on the same board. A 0.1- $\mu$ F supply decoupling capacitor must be placed as close to the supply pins as possible, preferably within 0.1 inch. For a split supply, a capacitor is required for both supplies. A 0.1- $\mu$ F capacitor placed directly between the supplies is also beneficial for improving system noise performance. If the output load is heavy, such as 16  $\Omega$  to 32  $\Omega$ , performance of the amplifier could begin to degrade. To drive such heavy loads, both channels of the OPA2836 device can be paralleled with their outputs isolated with 1- $\Omega$  resistors to reduce the loading effects.



#### 9.2.1.3 Application Curves

Figure 75 shows the THD+N performance with 100-k $\Omega$  and 300- $\Omega$  loads, and with A-weighting and with no weighting. Both loads show similar performance. With no weighting, the THD+N performance is dominated by the noise for both loads. A-weighting provides filtering that improves the noise, revealing the increased distortion with RL = 300  $\Omega$ .

Figure 76 and Figure 77 show the FFT output with a 1-kHz tone and 100-k $\Omega$  and 300- $\Omega$  loads. To show relative performance of the device versus the test set, one channel has the OPA836 device in-line between the generator output and the analyzer. The other channel is in "Gen Mon" loopback mode, which internally connects the signal generator to the analyzer input. With 100-k $\Omega$  load, Figure 76, the curves are indistinguishable from each other except for noise, which means the OPA836 device cannot be directly measured. With 300- $\Omega$  load, as shown in Figure 77, the main difference between the curves is that the OPA836 device shows slightly higher even-order harmonics, but the performance of the test set masks the odd-order harmonics.



#### OPA836, OPA2836

SLOS712I - JANUARY 2011 - REVISED OCTOBER 2016



#### 9.2.2 Active Filters

The OPA836 and OPA2836 devices are good choices for active filters. Figure 78 and Figure 79 show MFB and Sallen-Key circuits designed using the *WEBENCH<sup>®</sup> Filter Designer* to implement second-order low-pass Butterworth filter circuits. Figure 80 shows the frequency response.

Other MFB and Sallen-Key filter circuits offer similar performance. The main difference is the MFB is an inverting amplifier in the pass-band and the Sallen-Key is noninverting. The primary advantage for each is the Sallen-Key in unity gain has no resistor gain-error term, and thus no sensitivity to gain error, while the MFB has better attenuation properties beyond the bandwidth of the operational amplifier.

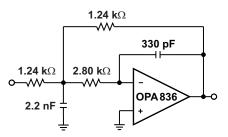


Figure 78. MFB 100-kHz Second-Order Low-Pass Butterworth Filter Circuit

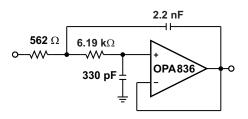


Figure 79. Sallen-Key 100-kHz Second-Order Low-Pass Butterworth Filter Circuit

#### 9.2.2.1 Application Curve

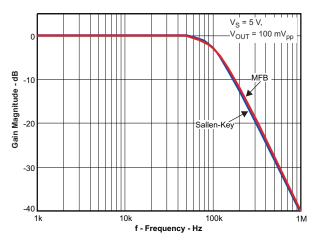


Figure 80. MFB and Sallen-Key Second Order Low-Pass Butterworth Filter Response



## **10** Power Supply Recommendations

The OPAx836 devices are intended to work in a supply range of 2.7 V to 5 V. Supply-voltage tolerances are supported with the specified operating range of 2.5 V (7% on a 2.7-V supply) and 5.5 V (10% on a 5-V supply). Good power-supply bypassing is required. Minimize the distance (< 0.1 inch) from the power-supply pins to high frequency, 0.1-µF decoupling capacitors. A larger capacitor (2.2 µF is typical) is used along with a high frequency, 0.1-µF supply decoupling capacitor at the device supply pins. For single-supply operation, only the positive supply has these capacitors. When a split supply is used, use these capacitors for each supply to ground. If necessary, place the larger capacitors farther from the device and share these capacitors among several devices in the same area of the PCB. Avoid narrow power and ground traces to minimize inductance between the pins and the decoupling capacitors. An optional supply decoupling capacitor across the two power supplies (for bipolar operation) reduces second harmonic distortion.

## 11 Layout

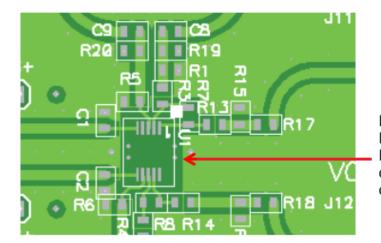
### 11.1 Layout Guidelines

The *OPA835DBV, OPA836DBV EVM* (SLOU314) can be used as a reference when designing the circuit board. TI recommends following the EVM layout of the external components near the amplifier, ground-plane construction, and power routing. General guidelines are listed as follows:

- 1. Signal routing must be direct and as short as possible into and out of the operational amplifier.
- 2. The feedback path must be short and direct avoiding vias if possible especially with G = +1.
- 3. Ground or power planes must be removed from directly under the negative input and output pins of the amplifier.
- 4. TI recommends placing a series output resistor as close to the output pin as possible. See *Series Output Resistor vs Capacitive Load* (Figure 17) for recommended values for the expected capacitive load.
- 5. A 2.2-µF power-supply decoupling capacitor must be placed within two inches of the device and can be shared with other operational amplifiers. For spit supply, a capacitor is required for both supplies.
- 6. A 0.1-μF power-supply decoupling capacitor must be placed as close to the power supply pins as possible, preferably within 0.1 inch. For split supply, a capacitor is required for both supplies.
- 7. The PD pin uses TTL logic levels. If the pin is not used, it must be tied to the positive supply to enable the amplifier. If the pin is used, it must be actively driven. A bypass capacitor is not necessary, but is used for robustness in noisy environments.

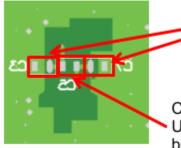


## 11.2 Layout Example



Dark green areas indicate regions of the PCB where the underlying Ground and Power Planes have been removed in order to minimize parasitic capacitance on the sensitive input and output nodes.

Figure 81. Top Layer



C3 and C7 are 0.1-µF bypass capacitors placed directly underneath the device power supply pins.

C5 is a bypass capacitor between the supply pins. Use this when configuring the amplifier with bipolar supplies to improve HD2 performance.

Figure 82. Bottom Layer



## **12 Device and Documentation Support**

#### 12.1 Device Support

#### 12.1.1 Development Support

WEBENCH® Filter Designer

#### 12.1.2 Related Documentation

For related documentation see the following:

OPA835DBV, OPA836DBV EVM (SLOU314).

#### 12.2 Related Links

Table 7 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

| PARTS   | PRODUCT FOLDER | SAMPLE & BUY | TECHNICAL<br>DOCUMENTS | TOOLS &<br>SOFTWARE | SUPPORT & COMMUNITY |
|---------|----------------|--------------|------------------------|---------------------|---------------------|
| OPA836  | Click here     | Click here   | Click here             | Click here          | Click here          |
| OPA2836 | Click here     | Click here   | Click here             | Click here          | Click here          |

#### Table 7. Related Links

#### 12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **12.4 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.5 Trademarks

E2E is a trademark of Texas Instruments. WEBENCH is a registered trademark of Texas Instruments. All other trademarks are the property of their respective owners.

#### 12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.7 Glossary

#### SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

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## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



4-Dec-2017

## PACKAGING INFORMATION

| Orderable Device | Status | Package Type | •       | Pins | •    | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp       | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|----------------------------|------------------|---------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty  | (2)                        | (6)              | (3)                 |              | (4/5)          |         |
| OPA2836ID        | ACTIVE | SOIC         | D       | 8    | 75   | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA2836IDGS      | ACTIVE | VSSOP        | DGS     | 10   | 80   | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG      | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA2836IDGSR     | ACTIVE | VSSOP        | DGS     | 10   | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG      | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA2836IDR       | ACTIVE | SOIC         | D       | 8    | 2500 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA2836IRMCR     | ACTIVE | UQFN         | RMC     | 10   | 3000 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA2836IRMCT     | ACTIVE | UQFN         | RMC     | 10   | 250  | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA2836IRUNR     | ACTIVE | QFN          | RUN     | 10   | 3000 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA2836IRUNT     | ACTIVE | QFN          | RUN     | 10   | 250  | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 2836           | Samples |
| OPA836IDBVR      | ACTIVE | SOT-23       | DBV     | 6    | 3000 | Green (RoHS<br>& no Sb/Br) | CU SN            | Level-1-260C-UNLIM  | -40 to 125   | QTL            | Samples |
| OPA836IDBVT      | ACTIVE | SOT-23       | DBV     | 6    | 250  | Green (RoHS<br>& no Sb/Br) | CU SN            | Level-1-260C-UNLIM  | -40 to 125   | QTL            | Samples |
| OPA836IRUNR      | ACTIVE | QFN          | RUN     | 10   | 3000 | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 836            | Samples |
| OPA836IRUNT      | ACTIVE | QFN          | RUN     | 10   | 250  | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 125   | 836            | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.



# PACKAGE OPTION ADDENDUM

4-Dec-2017

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF OPA2836 :

• Automotive: OPA2836-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal |                 |                    |    |      |                          |                          |            |            |            |            |           |                  |
|-----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device                      | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
| OPA2836IDGSR                | VSSOP           | DGS                | 10 | 2500 | 330.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| OPA2836IDR                  | SOIC            | D                  | 8  | 2500 | 330.0                    | 12.4                     | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| OPA2836IRMCR                | UQFN            | RMC                | 10 | 3000 | 180.0                    | 9.5                      | 2.3        | 2.3        | 1.1        | 2.0        | 8.0       | Q2               |
| OPA2836IRMCT                | UQFN            | RMC                | 10 | 250  | 180.0                    | 9.5                      | 2.3        | 2.3        | 1.1        | 2.0        | 8.0       | Q2               |
| OPA2836IRUNR                | QFN             | RUN                | 10 | 3000 | 180.0                    | 8.4                      | 2.3        | 2.3        | 1.15       | 4.0        | 8.0       | Q2               |
| OPA2836IRUNT                | QFN             | RUN                | 10 | 250  | 180.0                    | 8.4                      | 2.3        | 2.3        | 1.15       | 4.0        | 8.0       | Q2               |
| OPA836IDBVR                 | SOT-23          | DBV                | 6  | 3000 | 178.0                    | 9.0                      | 3.23       | 3.17       | 1.37       | 4.0        | 8.0       | Q3               |
| OPA836IDBVT                 | SOT-23          | DBV                | 6  | 250  | 178.0                    | 9.0                      | 3.23       | 3.17       | 1.37       | 4.0        | 8.0       | Q3               |
| OPA836IRUNR                 | QFN             | RUN                | 10 | 3000 | 180.0                    | 8.4                      | 2.3        | 2.3        | 1.15       | 4.0        | 8.0       | Q2               |
| OPA836IRUNT                 | QFN             | RUN                | 10 | 250  | 180.0                    | 8.4                      | 2.3        | 2.3        | 1.15       | 4.0        | 8.0       | Q2               |

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# PACKAGE MATERIALS INFORMATION

30-Mar-2017



| *All dimensions are nominal |              |                 |      |      |             |            |             |
|-----------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device                      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
| OPA2836IDGSR                | VSSOP        | DGS             | 10   | 2500 | 366.0       | 364.0      | 50.0        |
| OPA2836IDR                  | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |
| OPA2836IRMCR                | UQFN         | RMC             | 10   | 3000 | 205.0       | 200.0      | 30.0        |
| OPA2836IRMCT                | UQFN         | RMC             | 10   | 250  | 205.0       | 200.0      | 30.0        |
| OPA2836IRUNR                | QFN          | RUN             | 10   | 3000 | 210.0       | 185.0      | 35.0        |
| OPA2836IRUNT                | QFN          | RUN             | 10   | 250  | 210.0       | 185.0      | 35.0        |
| OPA836IDBVR                 | SOT-23       | DBV             | 6    | 3000 | 180.0       | 180.0      | 18.0        |
| OPA836IDBVT                 | SOT-23       | DBV             | 6    | 250  | 180.0       | 180.0      | 18.0        |
| OPA836IRUNR                 | QFN          | RUN             | 10   | 3000 | 210.0       | 185.0      | 35.0        |
| OPA836IRUNT                 | QFN          | RUN             | 10   | 250  | 210.0       | 185.0      | 35.0        |

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
  - A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
  - È Falls within JEDEC MO-178 Variation AB, except minimum lead width.



## LAND PATTERN DATA

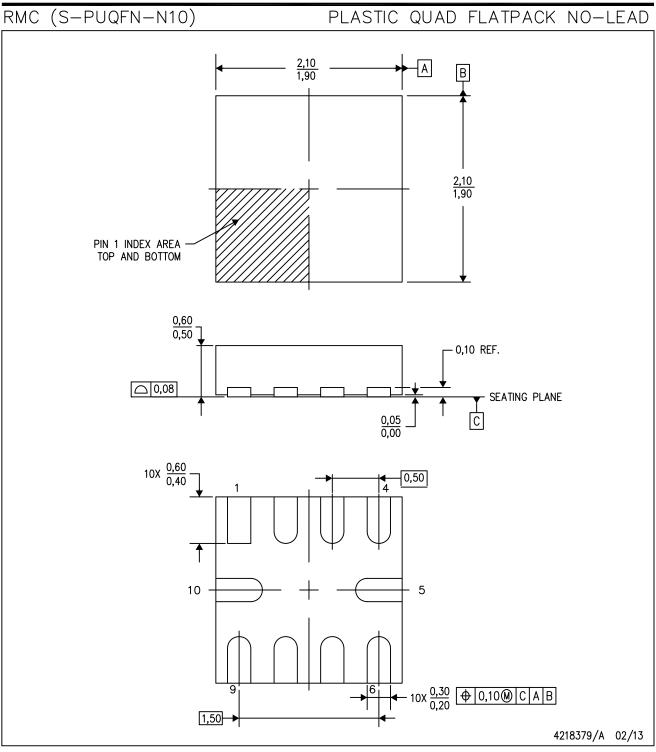


NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



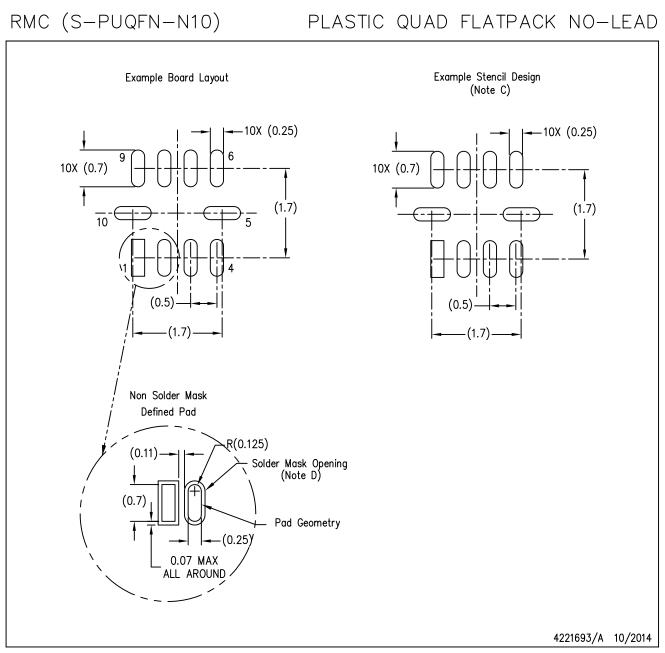
## **MECHANICAL DATA**



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.



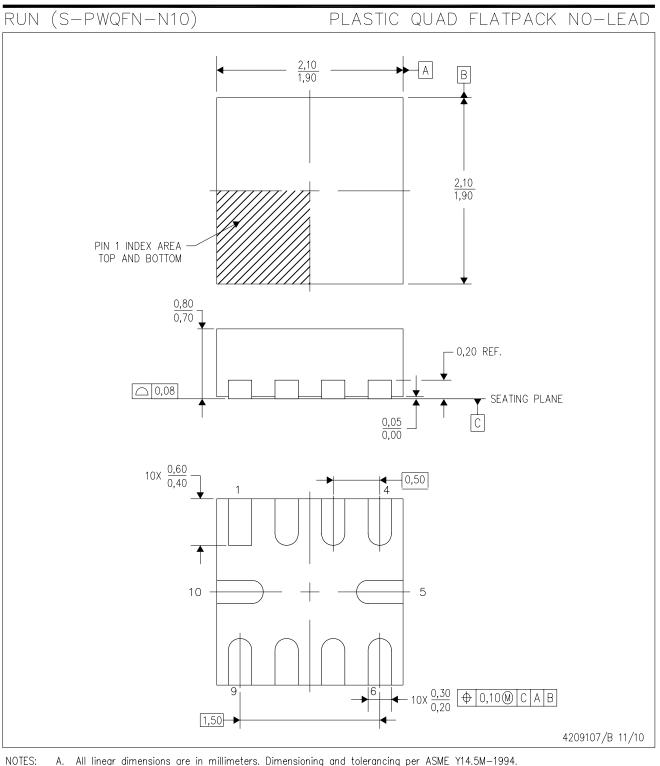


NOTES: A. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only.

- B. This drawing is subject to change without notice.
- C. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
   D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



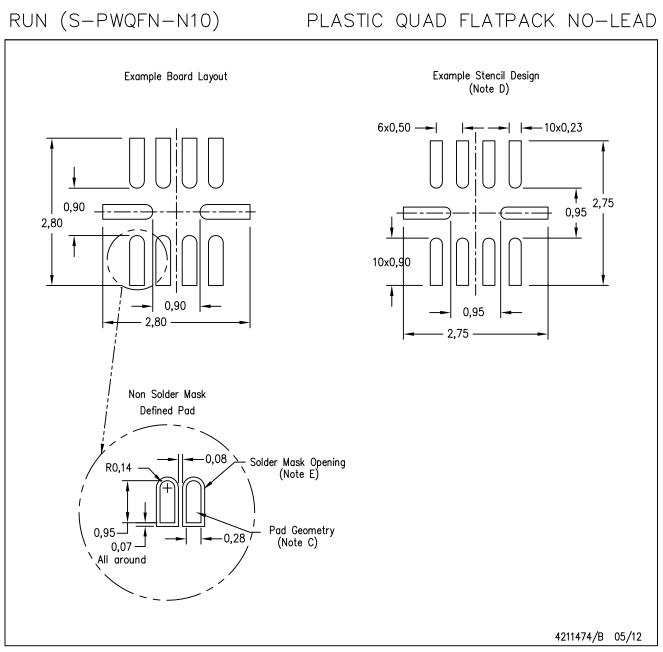
## **MECHANICAL DATA**



A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- В. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.





- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
   E. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
   E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation BA.



# DGS (S-PDSO-G10)

# PLASTIC SMALL OUTLINE PACKAGE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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